OICOM

SERVICE MANUAL

220MHz FM TRANSCEIVER IC-3SAT	
	······································

Icom Inc.

INTRODUCTION

This service manual describes the latest service information for the IC-3SAT 220 MHz FM TRANSCEIVER at the time of publication.

To upgrade quality, any electric or mechanical part and internal circuits are subject to change without notice or obligation.

DANGER

NEVER connect the transceiver to an AC outlet or to a DC power supply that uses more than 16 V. This will ruin the transceiver.

DO NOT expose the transceiver to rain, snow or any liquids.

DO NOT reverse the polarities of the power supply when connecting the transceiver.

DO NOT apply an RF signal of more than 20 dBm (100 mW) to the antenna connector. This could damage the transceiver's front end.

ORDERING PARTS

Be sure to include the following four points when ordering replacement parts:

- 1. 10-digit order numbers
- 2. Component part number and name
- 3. Equipment model name and unit name
- 4. Quantity required

<SAMPLE ORDER>

1150000800 IC SC1107 IC-3SAT MAIN UNIT 5 pieces 8810005720 Screw PH B0 M2 × 20 ZK IC-3SAT Rear panel 10 pieces

Addresses are provided on the inside back cover for your convenience.

REPAIR NOTE

- 1. Make sure a problem is internal before disassembling the transceiver.
- DO NOT open the transceiver until the transceiver is disconnected from a power source.
- DO NOT force any of the variable components. Turn them slowly and smoothly.
- DO NOT short any circuits or electronic parts. An insulated tuning tool MUST be used for all adjustments.
- 5. DO NOT keep power ON for a long time when the transceiver is defective.
- 6. DO NOT transmit power into a signal generator or a sweep generator.
- ALWAYS connect a 30 dB~40 dB attenuator between the transceiver and a deviation meter or spectrum analyzer when using such test equipment.
- READ the instructions of test equipment thoroughly before connecting equipment to the transceiver.



TABLE OF CONTENTS

SECTION	1	SPECIFICATIONS 1—	1
SECTION	2	INSIDE VIEWS2—	1
SECTION	3	BLOCK DIAGRAM 3 —	1
SECTION	4 - 1 4 - 2 4 - 3 4 - 4 4 - 5 4 - 6	CIRCUIT DESCRIPTION 4 — 1 ~ RECEIVER CIRCUITS 4 — TRANSMITTER CIRCUITS 4 — PLL CIRCUITS 4 — POWER SUPPLY CIRCUITS 4 — OTHER CIRCUITS 4 — CPU PORT ALLOCATIONS (LOGIC UNIT) 4 —	1 2 3 4 4
SECTION	5 5 - 1 5 - 2	MECHANICAL PARTS AND DISASSEMBLY. $5-1 \sim$ FRONT PARTS $5-$ CHASSIS PARTS $5-$	1
SECTION	6 6 - 1 6 - 2 6 - 3 6 - 4	ADJUSTMENT PROCEDURES $6-1$ ~PREPARATION BEFORE SERVICING $6-$ PLL ADJUSTMENT $6-$ RECEIVER ADJUSTMENT $6-$ TRANSMITTER ADJUSTMENT $6-$	1 2 3
SECTION	7 7 - 1 7 - 2 7 - 3 7 - 4	MAIN UNIT	1 2 4
SECTION	8	PARTS LIST 8 — 1 ~	7
SECTION	9 9 - 1 9 - 2 9 - 3	UT-51 TONE ENCODER UNIT	· 1
SECTION	10	VOLTAGE DIAGRAM 10 —	1

SECTION 1 SPECIFICATIONS

GENERAL

• Frequency coverage : 220.000~225.000 MHz

• Mode : F3 (FM)

• Selectable tuning step : 5, 10, 12.5, 15, 20, 25, 50, 100 kHz or 1 MHz

• Memory channels : 48 plus a call channel

Antenna impedance : 50 Ω

• Power supply requirement : 6~16 V DC negative ground or battery packs BP-81~BP-85 or battery case BP-90

• Current drain (at 13.8 V DC) : Receive 16 mA (power saved)

250 mA (max. audio output)

Transmit 550 mA (LOW 1) 1400 mA (HIGH)

• Usable temperature range : $-10 \,^{\circ}\text{C} \sim +60 \,^{\circ}\text{C} \, (+14 \,^{\circ}\text{F} \sim +140 \,^{\circ}\text{F})$

• Frequency stability : ± 15 ppm (-10 °C $\sim +60$ °C) (+14 °F $\sim +140$ °F)

• Dimensions : $49 (W) \times 102.5 (H) \times 35 (D) mm$

1.9 (W) \times 4.0 (H) \times 1.4 (D) in (Projections not included)

• Weight : 280 g (9.9 oz)

TRANSMITTER

• Output power (at 13.8 V DC) : High More than 5.0 W

Low 3.5/1.5/0.5 W (selectable)

• Modulation system : Variable reactance frequency modulation

• Max. frequency deviation : ±5 kHz

• Spurious emissions : Less than -60 dB

• Microphone impedance : $2 k\Omega$

■ RECEIVER

• Receive system : Double-conversion superheterodyne

• Intermediate frequencies : 1st 30.875 MHz

2nd 455 kHz

Sensitivity
 Selectivity
 0.22 μV for 12 dB SINAD
 More than 15 kHz/-6 dB

Less than 30 kHz/-60 dB

• Spurious rejection ratio : More than 60 dB

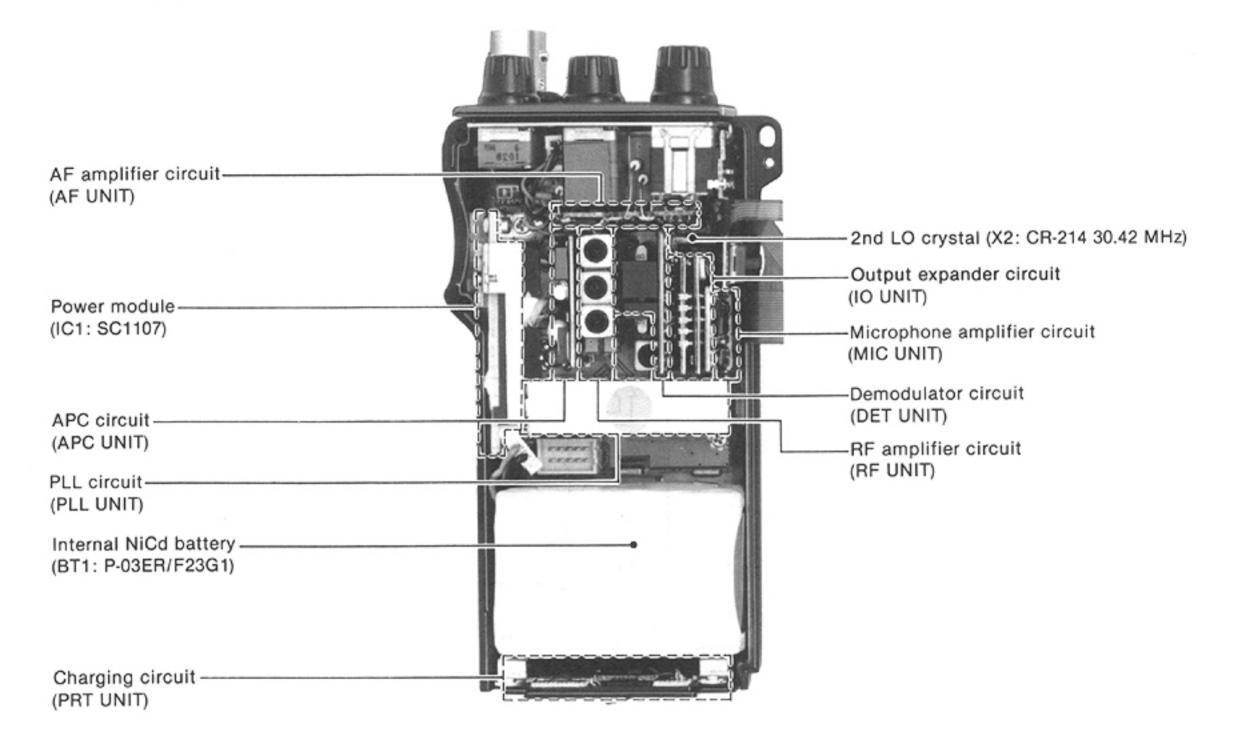
• Audio output power : More than 200 mW at 10 % distortion with an 8 Ω load

• Audio output impedance : 8Ω

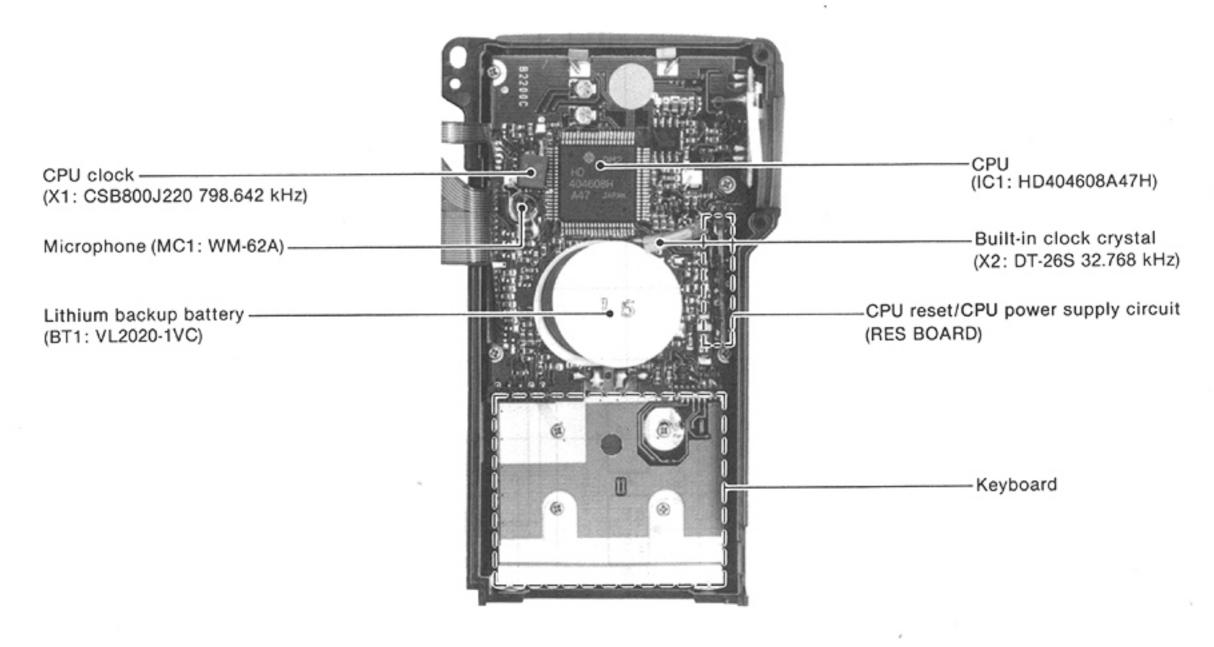
All stated specifications are subject to change without notice or obligation.

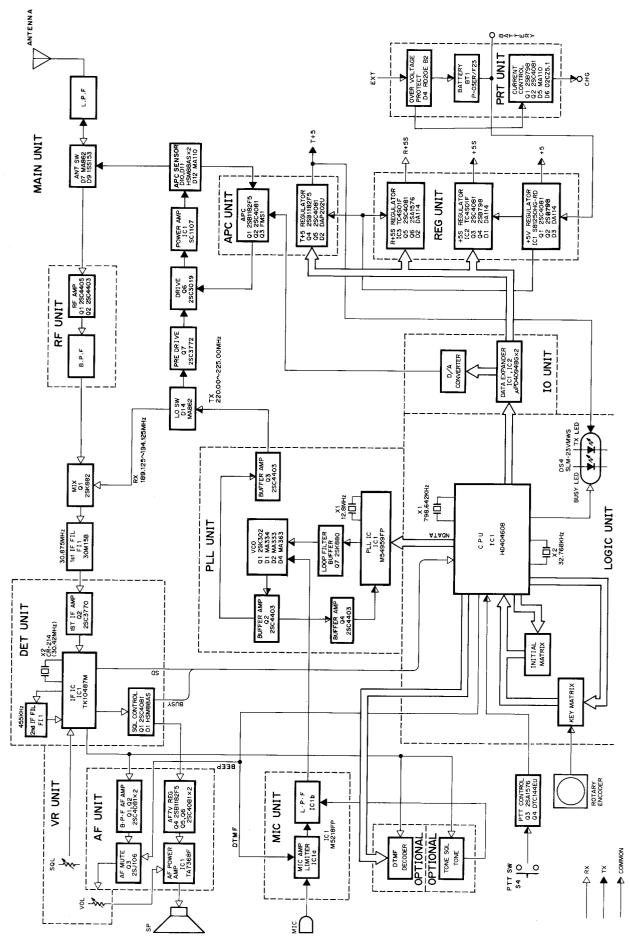
SECTION 2 INSIDE VIEWS

MAIN UNIT



LOGIC UNIT





SECTION 4 CIRCUIT DESCRIPTION

4-1 RECEIVER CIRCUITS

4-1-1 ANTENNA SWITCHING CIRCUIT (MAIN UNIT)

Received signals enter the antenna connector and pass through a bandpass filter (L3, L4, C21 \sim C25). The signals are applied to the antenna switching circuit (D7, D9, L5, L6, C26 \sim C28) and then to the RF UNIT via the RFIN signal line. The antenna switching circuit employs a two-stage $\lambda/4$ -type diode switching system.

The antenna switching circuit switches the transmit/receive circuit and functions as a low-pass filter while in receiving and becomes very high impedance while in transmitting.

4-1-2 RF CIRCUIT (RF UNIT)

The signals from the antenna switching circuit are applied to the bandpass filter (L1) and are then applied to the RF amplifier circuit (Q1, Q2).

The amplified signals are reapplied to the other bandpass filter (L2, L3). The bandpass filters suppress out-of-band signals. The signals are applied to the 1st mixer circuit (MAIN UNIT Q1).

4-1-3 1ST MIXER CIRCUIT (MAIN UNIT)

The signals from the RF circuit are mixed with the 1st LO signal from the PLL UNIT to produce a 30.875 MHz 1st IF signal.

4-1-4 1ST IF CIRCUIT (MAIN AND DET UNITS)

After passing through the matching circuit (L1), the 1st IF signal is applied to a pair of crystal filters (FI1) to suppress out-of-band signals. The 1st IF signal enters the DET UNIT and is amplified at the IF amplifier (Q2) and then applied to the 2nd mixer circuit.

4-1-5 2ND IF AND DEMODULATOR CIRCUITS (DET UNIT)

The 1st IF signal from Q2 is applied to the 2nd mixer section of IC1, and is mixed with the 2nd LO signal to be converted to a 455 kHz 2nd IF signal.

IC1 contains the 2nd mixer, local oscillator, limiter amplifier and quadrature detector circuits. The local oscillator section and X2 generate 30.42 MHz for the 2nd LO signal.

The 2nd IF signal from the 2nd mixer (IC1, pin 4) passes through the ceramic filter, FI1, where unwanted signals are suppressed. It is then amplified at the limiter amplifier section (IC1, pin 6) and applied to the quadrature detector section (IC1, pin 10 and ceramic discriminator X1) to demodulate the 2nd IF signal into an AF signal.

AF signal output from IC1 pin 11 is applied to the squelch circuit and de-emphasis circuit (R7, C24, C25). This deemphasis circuit is an integrated circuit with frequency characteristics of -6 dB/octave. The resulting signal is applied to the AF amp, optional tone squelch and optional DTMF decoder circuits.

RECEIVER CIRCUIT BLOCK DIAGRAM

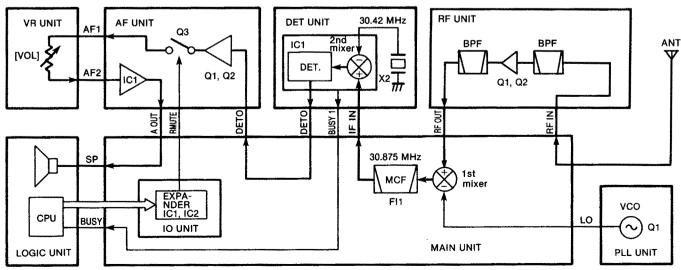


Fig. 1

4-1-6 AF AMP CIRCUIT (AF AND VR UNITS)

The AF signal is applied to Q1 and Q2 on the AF UNIT. Q1 is an active filter that functions as a high-pass filter to suppress tone signals for the tone squelch operation. Q2 is also an active filter that functions as a low-pass filter to suppress higher noise signals.

The filtered signal is applied to the [VOL] control (R1) on the VR UNIT via the AF mute circuit (Q3). When the squelch is closed, Q3 cuts the AF signal as the AF mute switch. The AF signal is power-amplified at the AF power amplifier (IC1) to drive the speaker.

The AF voltage regulator (Q4~Q6) supplies power to the AF power amplifier. The AFS signal from the MAIN UNIT controls Q6 and mutes AF output while receiving no signal or no specified tone/DTMF signal.

4-1-7 SQUELCH CIRCUIT (DET UNIT)

Some of the noise components in the AF signal from IC1 pin 11 are applied to IC1 pin 13 via C11, R8, C13 and C14. The [SQL] control (R2) on the VR UNIT adjusts the pin 13 input level.

The active filter section in IC1 amplifies noise components of frequencies of 20 kHz and above, and outputs the resulting signals from pin 14. Output signals are rectified by D1 and are converted to DC voltage.

The rectified voltage triggers the squelch switch (Q1). The collector of Q1 outputs the squelch signal. The signal is applied to the CPU (IC1, pin 27) on the LOGIC UNIT through the BUSY signal line. The CPU outputs the RMUTE and BUSY LED signals.

The RMUTE signal, decoded at the output expander (IC1) on the IO UNIT, activates the AF mute circuit (Q3) on the AF UNIT to cut the AF signal. The BUSY LED signal is applied to Q1 on the LOGIC UNIT, turning OFF the receive indicator.

4-2 TRANSMITTER CIRCUITS

4-2-1 MICROPHONE AMPLIFIER (MIC UNIT)

AF signals from the built-in condenser microphone or from the [MIC] jack are applied to IC1 pin 3, and are pre-emphasized to +6 dB/octave through C6 and R4 connected to pin 2. IC1 functions as the microphone amplifier and the limiter.

The output signals from IC1 pin 1 pass through the splatter filter circuit (IC1 pins 5 and 6) where signals of 3 kHz and above are attenuated. IC1 pin 7 then outputs the signals. The signals are applied to the modulation circuit (PLL UNIT, D4) to produce an FM signal.

The VCO circuit (Q1, D1, D2) oscillates the transmit frequency with AF signal modulation as a PLL output.

4-2-2 DRIVE AMPLIFIER (MAIN UNIT)

The PLL output (LO signal line), buffer-amplified at Q3 on the PLL UNIT, is applied to the transmit/receive switching circuit (D14). The PLL output is then amplified at the predrive amplifier (Q7) and the drive amplifier (Q6).

The voltage controlled by the APC circuit is applied to the collector of Q6 and Q7 to protect the RF power module from damage by an antenna mismatch.

4-2-3 RF POWER AMPLIFIER (MAIN UNIT)

IC1 is a power module which provides stable 5 W output power.

An RF signal from the drive amplifier (Q6) is applied to IC1 pin 1. The amplified signal is output from pin 4, and applied to the antenna connector through the diode switching and bandpass filter circuits.

TRANSMITTER CIRCUIT BLOCK DIAGRAM

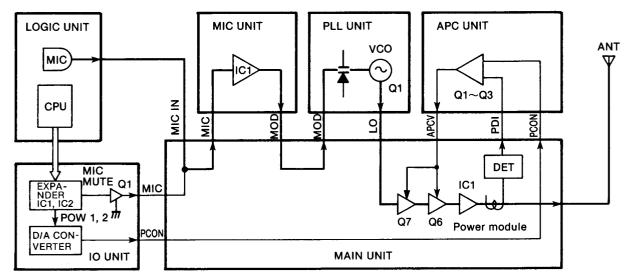


Fig. 2

4-2-4 APC CIRCUIT (MAIN AND APC UNITS)

The APC circuit protects the power module (IC1) from a mismatched output load and selects HIGH and LOW output power.

The output power level from the power module (IC1) is detected at the APC detector (D10 \sim D12). When antenna impedance is matched at 50 Ω , the detected level is at a minimum. However, when antenna impedance is mismatched, the detected voltage is higher than when it is matched.

When the antenna impedance is mismatched, the base voltage of Q3b (APC UNIT) is higher than the other base voltage of Q3a (reference voltage). Q3b decreases the collector current of Q1 using Q2. Collector current of Q1 is used at the drive amplifiers (Q6, Q7) on the MAIN UNIT. Hence, when the antenna impedance is mismatched, the output power is decreased.

The circuit which selects output power uses the APC circuit. The PCON voltage from the IO UNIT shifts the reference voltage, changing the output power to HIGH or LOW $1\sim3$.

4-2-5 ANTENNA SWITCHING CIRCUIT (MAIN UNIT)

When transmitting, D7 and D9 are turned ON. The RF output signal is not applied to the receiver circuit, passing through D9 and C60, the bandpass filter (L3, L4, C21 \sim C25) and then to the antenna. The bandpass filter suppresses high harmonic components.

4-3 PLL CIRCUITS

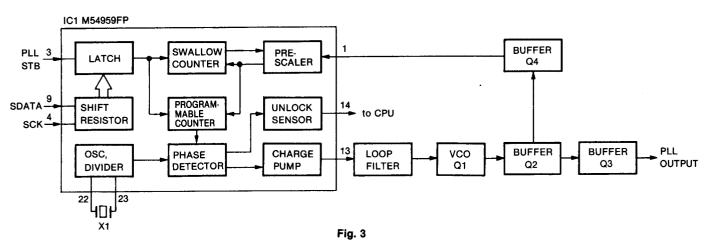
4-3-1 GENERAL (PLL UNIT)

The PLL circuit, using a one chip modulus prescaler (IC1), directly generates the transmit and 1st LO frequencies with the VCO (Q1). The modulus prescaler (IC1) sets the dividing ratio based on serial data from the CPU, and compares the phases of a VCO signal and the reference oscillator frequency. It detects the out-of-step phase and outputs it. The reference frequency is oscillated at X1.

4-3-2 REFERENCE OSCILLATOR CIRCUIT (PLL UNIT)

A reference frequency is produced by the local oscillator section of IC1 and X1. C21 provides frequency control.

PLL CIRCUIT



4-3-3 LOOP FILTER CIRCUIT (PLL UNIT)

Phase-detected signals from IC1 pin 13 are converted to DC voltage by a lag-lead loop filter (R10, R20, C12, C13).

The frequency at which the VCO oscillates is controlled by varactor diodes (D1, D2). DC voltage (PLL lock voltage) is provided through the buffer amplifier (Q7).

4-3-4 VCO CIRCUIT (PLL UNIT)

The VCO circuit (Q1) generates the receive and transmit frequencies and makes an FM modulation.

D3 changes the inductive reactance of the VCO, shifting the receive and transmit frequencies using a control signal from IC1 pins 10 and 11. Varactor diodes (D1, D2) provide frequency control. The buffer amplifiers (Q2, Q3, Q4) do not affect the PLL output signal from VCO oscillation.

4-3-5 UNLOCK SENSOR CIRCUIT (PLL UNIT)

When the PLL circuit is unlocked, IC1 pin 14 is "HIGH" and the "HIGH" signal is applied to the CPU pin 7 as an unlock signal.

4-4 POWER SUPPLY CIRCUITS

4-4-1 VOLTAGE LINES

LINE	DESCRIPTION
Vcc	The internal or attached battery pack voltage or external DC power passed through the power switch.
+5	Common 5 V converted from the Vcc line at Q1 and Q2 on the REG UNIT using IC1 output as the reference voltage.
+5\$	5 V controlled by the power saver function. This voltage is converted from Vcc line at Q3 and Q4 on the REG UNIT using IC2 output as the reference voltage.
R+5S	Receive 5 V controlled by the power saver function and SEND signal line. This voltage is converted from Vcc line at Q5 and Q6 on the REG UNIT using IC3 output as the reference voltage.
T+5	Transmit 5 V controlled by the TMUTE signal line. This voltage is converted from Vcc line at Q4 and Q5 on the APC UNIT.
AF 7 V	AF amp power source controlled by the AFS signal line. R14/R15 provides reference voltage.

4-4-2 CPU POWER SUPPLY CIRCUIT (LOGIC UNIT)

When the internal or attached battery pack is discharged, voltage is applied to the CPU (IC1) pin 73 via R29 from the lithium backup battery (BT1) installed in the transceiver to provide backup for the memory contents.

When the internal or attached battery pack voltage or external DC power is applied to the transceiver, BT1 is charged using the current regulator (Q3).

4-4-3 +5S AND R+5S SWITCHING CIRCUITS (REG UNIT)

The IC-3SAT has a power saver to reduce current consumption to approx. 1/4.

The PSC (Power Saver Control) signal is applied to IC2. IC2 controls +5S regulator (Q3, Q4, D1) to turn ON and OFF +5S voltage.

PSC and SEND signals are applied to IC3. IC3 controls R+5S regulator (Q5, Q6, D2). R+5S turns OFF during power saved period or transmitting.

4-4-4 CHARGING CIRCUIT (PRT UNIT)

Voltage from the [DC 13.8V] jack is applied to current control circuit (Q1, Q2, D5, D6) to charge an internal or attached battery pack (except the BP-85).

When the external battery pack is attached, the current from D2 charges the attached battery pack. When the external battery pack is removed, the current from D2 charges the internal battery pack.

The IC-3SAT has an external battery switch. When a battery pack is attached, this switch connects the external battery to the charging circuit.

Over voltage protector (D4) decreases the transceiver circuit damage from over voltage and reverse polarity connections of the power supply.

4-5 OTHER CIRCUITS

4-5-1 S/RF INDICATOR CIRCUIT (DET, MAIN AND LOGIC UNITS)

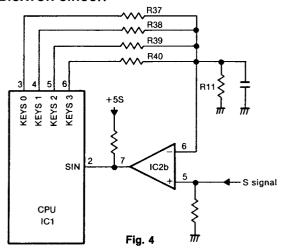
A portion of the 2nd IF signal is output from IC1 pin 12 on the DET UNIT via the SD signal line. The signal is rectified at D1 on the MAIN UNIT to obtain an S-indicator signal. The S-indicator signal is applied to IC2b pin 5 on the LOGIC UNIT.

IC2b pin 6 receives an S-indicator reference signal from the CPU KEYS0~3 terminals via the D/A converter (R11, R37~R40). The CPU terminals increase the reference signal level.

When the D/A converted level becomes greater than the S-indicator level, IC2b pin 7 becomes "LOW." The CPU detects the signal strength level using the KEYS0~3 terminal outputs and indicates the signal strength level on the function display when receiving the "LOW" signal.

While transmitting, the S/RF indicator indicates the selected output power.

S INDICATOR CIRCUIT



4-5-2 DISPLAY BACKLIGHT CIRCUIT (LOGIC UNIT)

When the [LIGHT] switch is pushed, pin 77 of the CPU outputs "HIGH." The signal is applied to Q1 to light up the backlight LEDs (DS2, DS3).

4-5-3 SUBAUDIBLE TONE ENCODER CIRCUIT

This function can be activated only when an optional UT-50 TONE SQUELCH UNIT or UT-51 PROGRAMMABLE TONE ENCODER UNIT is installed.

A tone signal is applied to the splatter filter circuit on the MIC UNIT via the TONE signal line. R10 on the UT-50 and R5 on the UT-51 adjust the subaudible tone deviation.

4-5-4 DTMF ENCODER CIRCUIT (LOGIC UNIT)

This function can be activated only when the matrix KEYS1 → KEYI1 is OPEN. (an optional UT-49 DTMF DECODER UNIT is installed.)

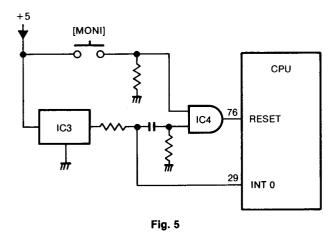
Pins 70 and 71 of the CPU (TONEC/TONER) output a DTMF code signal. R16 adjusts the DTMF code signal deviation. The signal is also output to the AF UNIT via R17.

4-5-5 CPU RESET CIRCUIT (LOGIC UNIT)

IC3 detects +5 voltage. When the +5 voltage line becomes 5 V, IC3 turns INT0 "HIGH" and the CPU (IC1) restarts operation.

The CPU is reset when IC1 pin 76 becomes "HIGH." The AND gate IC (IC4) outputs a reset signal when both input terminals are "HIGH." One terminal is "HIGH" when the [MONI] switch is pushed and the other (INTO line) is "HIGH" when the power is turned ON.

RESET CIRCUIT



4-5-6 TRANSMIT/RECEIVE INDICATOR CIRCUIT (LOGIC UNIT)

The transmit/receive indicator (DS4) uses a 2-input LED and lights up in red or green.

The indicator lights up in red as the transmit indicator while transmitting using the T+5 voltage.

The indicator lights up in green as the busy indicator while the squelch opens using CPU pin 78 output via the inverter (Q2).

4-5-7 CLOCK OSCILLATOR CIRCUIT (LOGIC UNIT)

IC1 oscillates the 798.642 kHz CPU system clock signal using X1. IC1 oscillates the 32.768 kHz clock signal for the built-in clock using X2.

4-6 CPU PORT ALLOCATIONS (LOGIC UNIT)

INPUT PORT

PORT NUMBER	PIN NUMBER	DESCRIPTION
D4 [PTT]	1	Inputs a signal on the PTT line. This port becomes "LOW" when the PTT switch is pushed.
D5 [SIN]	2	Inputs S-meter-compared signal from IC2b to indicate the CPU counting level to the S-indicator in the function display.
D10 [UL]	7	Detects a PLL unlock signal. When the signal is "HIGH," the PLL is unlocked.
D12, D13 [DIAL UP/DN]	9, 10	Input port for the up/down signal of the tuning control.
R10~R13 [KEYI0~ KEYI3]	19~22	These are input ports for the initial and key matrices.
R20~R23 [KEYR0~ KEYR3]	23~26	These are input ports for the keyboard and DTMF code from the UT-49.
R30 [BUSY]	27	Detects a squelch signal. The signal is "HIGH" when the squelch opens.
R31 [OPT]	28	Input port for an optional unit. This port becomes "HIGH" when the tone squelch opens. (UT-50) This port becomes "LOW" when the UT-51 is installed.
R32 [INT0]	29	Detects a signal for the standby mode of the CPU. The CPU enters the standby mode when the port becomes "LOW."
R33 [INT1]	30	The CPU decodes received DTMF code when this port becomes "LOW."

• OUTPUT PORT

PORT NUMBER	PIN NUMBER	DESCRIPTION
D0 [LAMP0]	77	Becomes "HIGH" when the backlight LEDs light up.
D1 [BUSY LED]	78 Outputs a signal for lighting up green the transmit/receive indicator. This port becomes "LOW" while receiving. (squelch opens)	
D3 [TOE]	80	Outputs an enable signal for the UT-49.
D6~D9 [KEYS0~ KEYS3]	3~6	Outputs a strobe signal for the keyboard, initial and key matrices and D/A converter counting signal alternately in an interval.
R00 [SCK]	15	Outputs clock signals for serial data.
R01 [IO STB]	16	Outputs a strobe signal for serial data to the expander ICs.
R02 [SDATA]	17	Outputs serial data synchronized with the SCK signal.
R03 [PLL STB]	18	Outputs a strobe signal for serial data to the PLL IC.

• OUTPUT EXPANDER (IO UNIT, IC1)

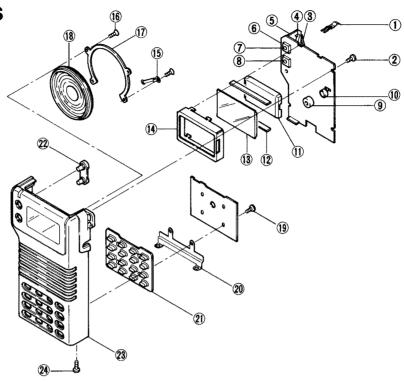
PORT NUMBER	PIN NUMBER	DESCRIPTION
Q1 [AF ON]	4	Outputs an AF mute signal for AF power amplifier.
Q2 [MIC MUTE]	5	Outputs a microphone mute signal. When transmitting a tone signal, the MIC signal line goes to ground.
Q3 [RMUTE]	6	Outputs a receive mute signal for the AF mute circuit. When emitting a beep tone, this port outputs the mute signal and the AF ON port does not output it.
Q4 [TMUTE]	7	Outputs a control signal for T+5 V regulator.
Q5 [SEND]	14	Outputs transmit/receive switching signals. This port becomes "HIGH" while transmitting.
Q6 [PSC]	13	This port becomes "HIGH" while the power saver function is activated.
Q7 [CPC]	12	Outputs a control signal to cut off the loop filter while the power saver function is activated.

• OUTPUT EXPANDER (IO UNIT, IC2)

PORT NUMBER	PIN NUMBER	DESCRIPTION
Q5, Q6 [POW 1, POW 2]	13, 14	Outputs a control signal for the output power selecting circuit. This signal is converted into PCON voltage (APC reference voltage) using the D/A converter (R2~R6).

SECTION 5 MECHANICAL PARTS AND DISASSEMBLY

5-1 FRONT PARTS



LABEL Number	ORDER NO.	DESCRIPTION		LABEL NUMBER	ORDER NO.	DESCRIPTION	QTY.
1	8930016400	756 LOGIC Ground spring plate	2	14	8930015960	756 LCD holder	1
2	8810001700	Screw PH B0 No. 0-3 M1.4×3	4	15	8930016410	756 Speaker ground lag	1
3	8930015790	PTT Ground spring plate	1	16	8810005740	Screw FH B0 No. 0 M2×3	4
4	8930014880	752 P.C. Board holder	1	17)	8930014810	752 Speaker plate	1
(5)	2230000770 Switch [F] SW-104 (SKHUPE004B)		1	18	2510000450	Speaker EAS-3P123D	1
6	2230000770	Switch [PTT] SW-104 (SKHUPE004B)		19	8810001700	Screw PH B0 No. 0-3 M1.4×3	4
1	2260001150	Switch [H/L/DTMF] SW-103 (SKHUPC007B)		20	8510006050	Key shield	1
8	2260001150	Switch [MONI] SW-103 (SKHUPC007B)	1	21)	8010009080	756 Keyboard	1
9	8930014940	752 MIC holder	1	22	8610005970	Knob K138 [H/L/DTMF], [MONI]	2
10	7700000860	Microphone WM-62A	1	60	0010005171	756 Front panel (F)-1	1
11	8010009070	756 Reflector plate	1	23	8210005171	(incl. Front plate and 756 lens)	'
12	8930015920	LCD contact strip SRCN-756		24	8810005890	Screw FH M2×4 ZK	2
13	6910003910	LCD LCD2439 (incl. shield)	1				

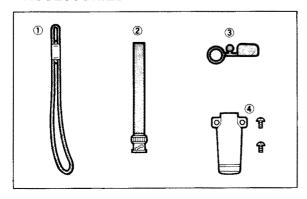
Screw abbreviations

PH: Pan head

B0: Self-tapping screw

ZK: Black

• ACCESSORIES



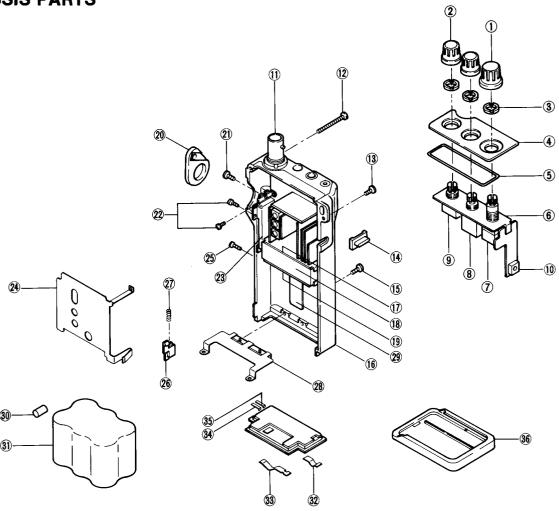
LABEL Number	ORDER NO.	DESCRIPTION	QTY.
1	8010008970	Handstrap HK-002	1
2	Optional product	FA-215BA FLEXIBLE ANTENNA	1
3	8930014961	752 Rainproof cap-1	1
4	8010008620	752 Belt clip	1
(5)	8810005730	Screw BuH M3×3 ZK BS	2

Screw abbreviations

BuH: Button head

BS: Brass ZK: Black

5-2 CHASSIS PARTS



LABEL NUMBER	ORDER NO.	DESCRIPTION	QTY.	LABEL Number	ORDER NO.	DESCRIPTION	QTY.
1	8610005790	Knob N147 [TUNING]	1	18	8510005850	752 PLL case	1
2	8610005780	Knob N146 [SQUELCH], [PWR/VOL]	2	19	8510006170	755 PLL cover	1
3	8830000550	VR nut (E)	3	20	8930015940	756 PTT switch rubber	1
4	8210005071	756 TOP panel-1	1	21)	8810000120	Screw PH M2.6×3	1
<u>(5)</u>	8930014950	752 TOP seal	1	22	8810005860	Screw PH No. 0 M2×3 Ni	5
6	8930014801	752 VR plate-1	1	23	8930014840	752 Module shield plate	1
7	2260000890	Rotary switch [TUNING] SRBM1L040A	1	24	8510006180	755 MAIN shield plate	1
		Variable resistor [PWR/VOL]		25	8810005700	Screw PH No. 0 M2×4 ZK	1
8	8 7210001440 RK097111101NA (10KA)	1	26	8930014922	752 Release button-2	1	
		Variable resistor [SQUELCH]		27)	8930014820	Release spring (M)	1
9	7210001450	RK0971110051A (10KB)	1	28	8930015980	Joint plate	1
10	2260001150	Switch [LIGHT] SW-103 (SKHUPC007B)	1	29	8930016570	756 BP holder plate	1
11)	6510008620	Antenna connector BNC-RM-F	1	30	8930016590	BP rubber	1
12	8810005720	Screw PH B0 M2 × 20 ZK	2	31)	3030000270	NiCd battery P-03ER/F23G1	1
13	8810000100	Screw PH M2 × 4 ZK	1	32	8930014852	752 Battery terminal-2	3
14	8930014911	Light switch-1 rubber	1	33	8930016583	756C terminal-3	1
15	8810005890	Screw FH M2×4 ZK	2	34)	8930016970	756A Contact	1
16	8010009064	756 Rear panel-4	1	35)	8930016980	756B Contact	1
17)	8510005830	CO-PLL cover	1	36	Optional product	BOTTOM CAP-2	1

Screw abbreviations

PH: Pan head

FH: Flat head

B0: Self-tapping screw

ZK: Black

Ni: Nickel

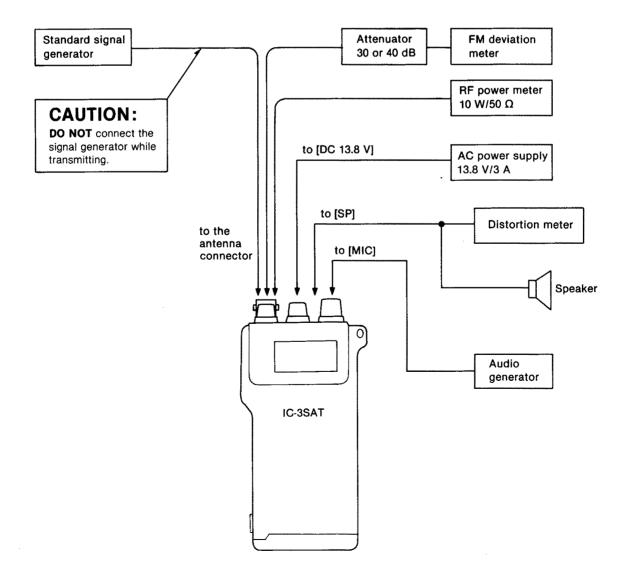
SECTION 6 ADJUSTMENT PROCEDURES

6-1 PREPARATION BEFORE SERVICING

■ REQUIRED TEST EQUIPMENT

EQUIPMENT	GRADE AND RANGE		EQUIPMENT	GRADE AND RANGE		
AC power supply	Output voltage : 13.8 V DC		DC voltmeter	Input impedance	: 50 kΩ/DC or better	
	Current capacity :	: 3 A or more	AC milli-voltmeter	Measuring range	: 10 mV~10 V	
RF power meter	1	: 1∼10 W : 220∼250 MHz	External speaker	Impedance	: 8 Ω	
(terminated type)	Impedance SWR	: 50 Ω : Less than 1.2 : 1	Audio generator	Frequency range Output level	: 300~3000 Hz : 1~500 mV	
Frequency counter	Frequency range : 0.1~250 MHz Frequency accuracy: ±1 ppm or better Sensitivity : 100 mV or better		Attenuator	Power attenuation Capacity	: 30 or 40 dB : 10 W or more	
		: 100 mV or better	Distortion meter	Measuring range	: 0.1~20 %	
Oscilloscope]	: DC~20 MHz : 0.01~10 V	FM deviation meter	Frequency minimum Measuring range	: 250 MHz : 0~±10 kHz	
Standard signal generator (SSG)	1	: 0.1~250 MHz : -127~-17 dBm (0.1 µV~32 mV)				

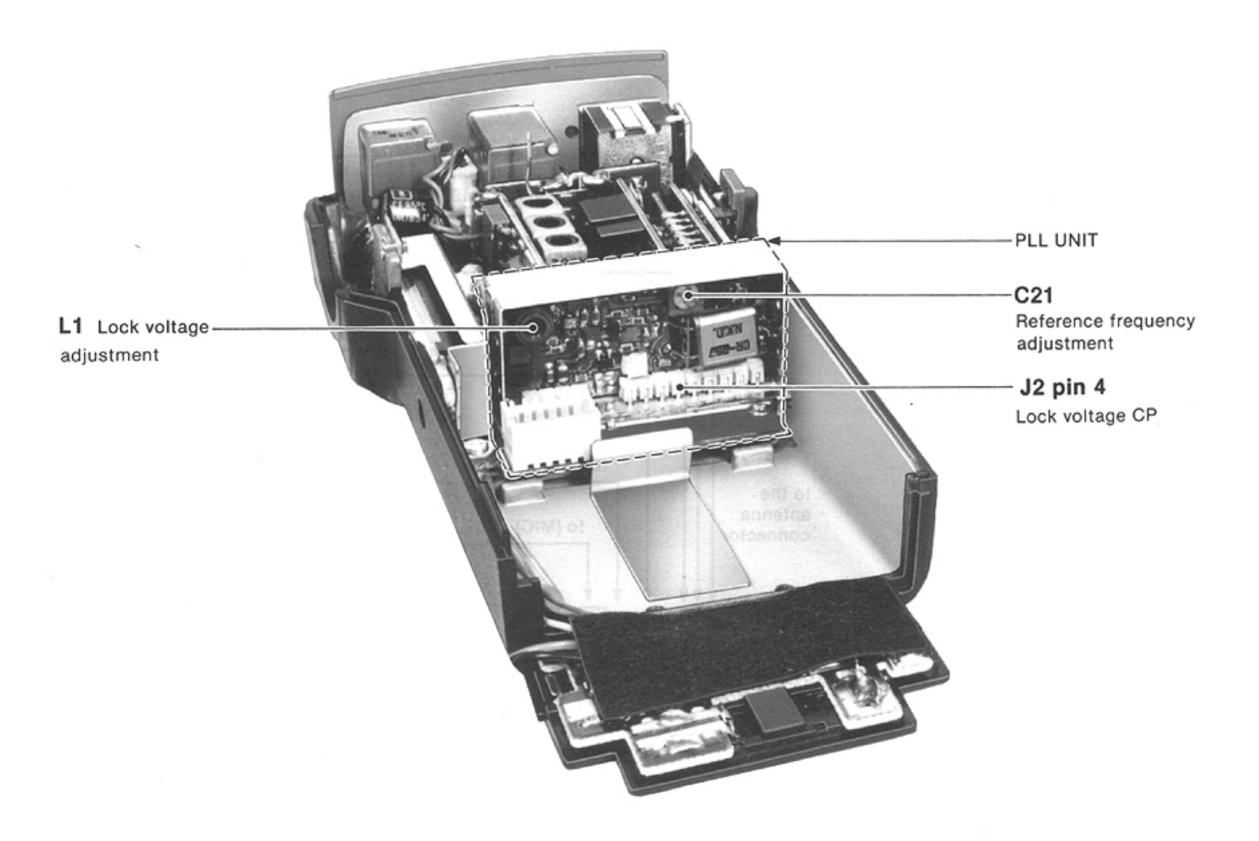
CONNECTION



6-2 PLL ADJUSTMENT

ADJUSTME	NT	ADJUSTMENT CONDITIONS	N	MEASUREMENT			POINT	
ADJUSTME	NI	ADJUSTMENT CONDITIONS	UNIT	LOCATION	VALUE	UNIT	ADJUST	
LOCK VOLTAGE	1	Displayed frequency: 220.00 MHz Simplex Receiving	PLL	Connect the oscilloscope to J2 pin 4.	1.6 V DC	PLL	L2	
	2	Transmitting			1.6 V±0.5 V DC		Verify	
REFERENCE FREQUENCY	1	 Displayed frequency: 222.50 MHz Connect the RF power meter or a 50 Ω dummy load. Transmitting 	Top panel	Loosely couple the frequency counter to the antenna connector.	222.5000 MHz	PLL	C21	

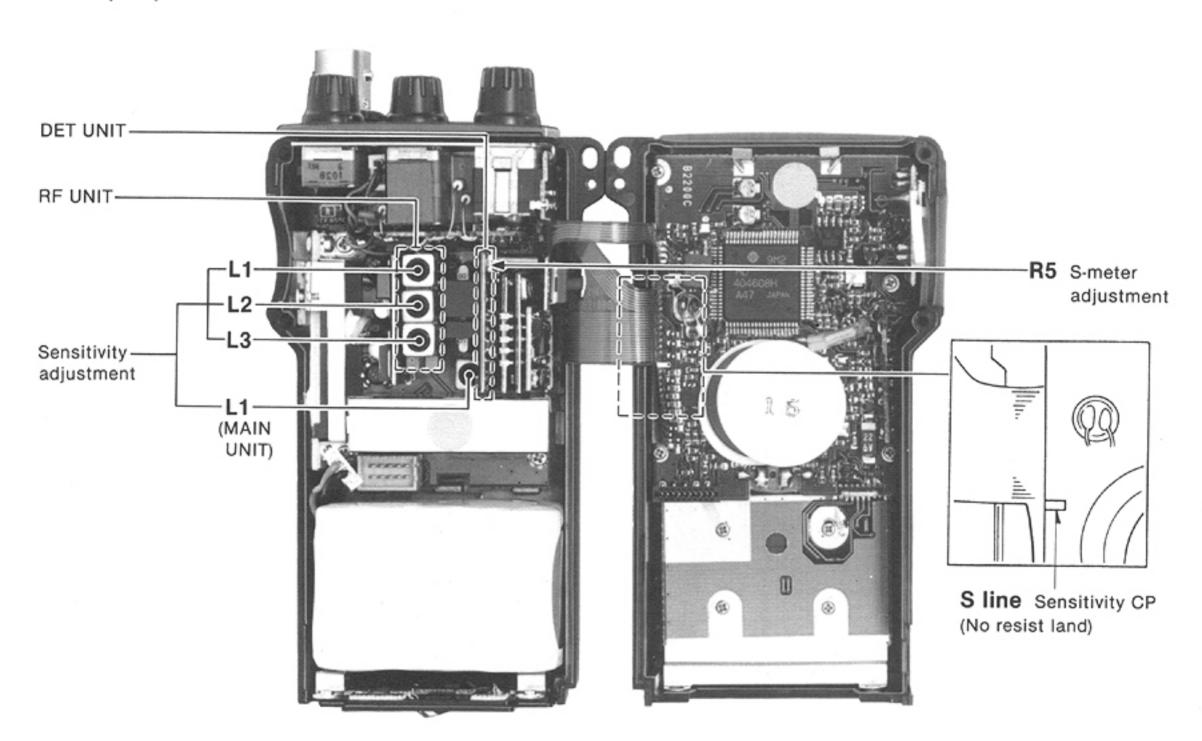
PLL UNIT



6-3 RECEIVER ADJUSTMENT

ADJUSTME	NT	ADJUSTMENT CONDITIONS	MEASUREMENT		VALUE	ADJUSTMENT POINT	
ADJUSTME	.NI	ADJUSTMENT CONDITIONS	UNIT LOCATION		VALUE	UNIT	ADJUST
SENSITIVITY	1	 Displayed frequency: 222.50 MHz [SQL] control : Max. CCW Set the signal generator; Level : 0.32 μV (-117 dBm) Modulation: 1 kHz Deviation : ±3.5 kHz Receiving 	LOGIC	Connect the DC voltmeter to the land of the S line.	Maximum	RF	L1, L2, L3
S-METER	1	 Displayed frequency: 222.50 MHz Set the signal generator; Level : 0.32 µV (-117 dBm) Modulation: 1 kHz Deviation : ±3.5 kHz Receiving 	Function display	S/RF indicator	2 bars (S2)	DET	R5

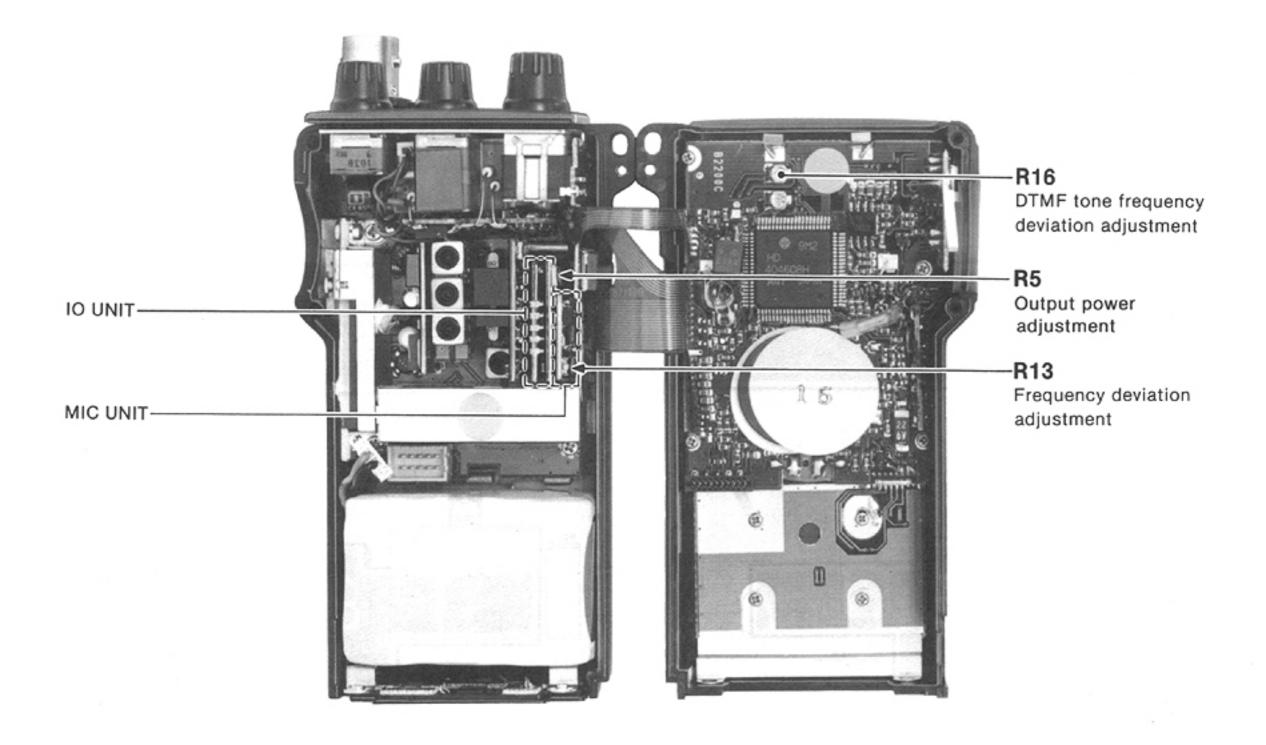
LOGIC, RF, MAIN AND DET UNITS



6-4 TRANSMITTER ADJUSTMENT

ADJUSTMENT		ADJUSTMENT CONDITIONS	MEASUREMENT		VALUE	ADJUSTMENT POINT	
		ADJUSTMENT CONDITIONS	UNIT LOCATION		VALUE	UNIT	ADJUST
OUTPUT POWER	1	Displayed frequency: 222.50 MHz Output power : HIGH Simplex Transmitting	Top panel	Connect the RF power meter to the antenna connector.	5.0 W	10	R5
	2	Output power : LOW 1			0.25~1.0 W		Verify
	3	Output power : LOW 2	-		Approx. 1.5 W		Verify
	4	Output power : LOW 3			Approx. 3.5 W		Verify
FREQUENCY DEVIATION	1	Displayed frequency: 222.50 MHz Output power : HIGH Apply an AF signal to the [MIC] jack. 170 mV/1 kHz Set the FM deviation meter. HPF : 50 Hz LPF : 20 kHz De-emphasis: OFF Detector : (P-P)/2 Transmitting	Top panel	Connect the FM deviation meter to the antenna connector via the attenuator.	±4.8 kHz	MIC	R13
DTMF TONE FREQUENCY DEVIATION	1	 Displayed frequency: 222.50 MHz Push and hold the [PTT] switch and then push the [D] key. 	Top panel	Connect the deviation meter to the antenna connector via the attenuator.	±3.5 kHz	LOGIC	R16

IO, MIC AND LOGIC UNITS

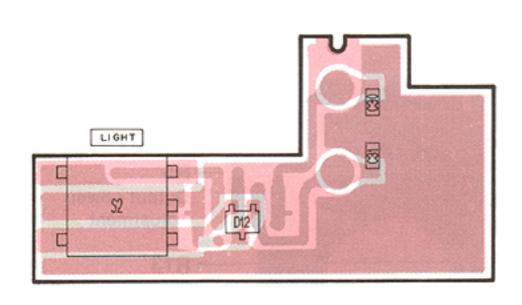


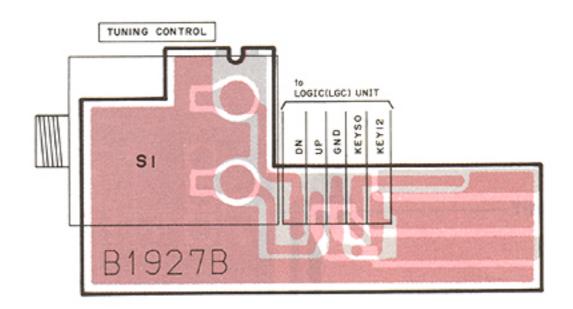
SECTION 7 BOARD LAYOUTS

7-1 LOGIC DAUGHTER UNITS

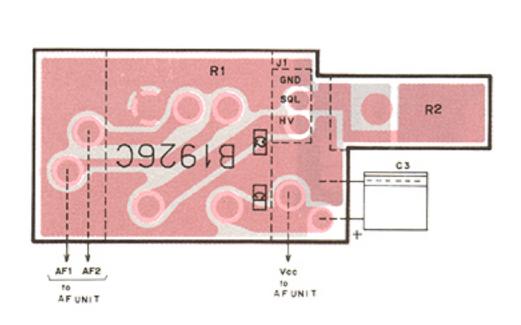
TUNING BOARD

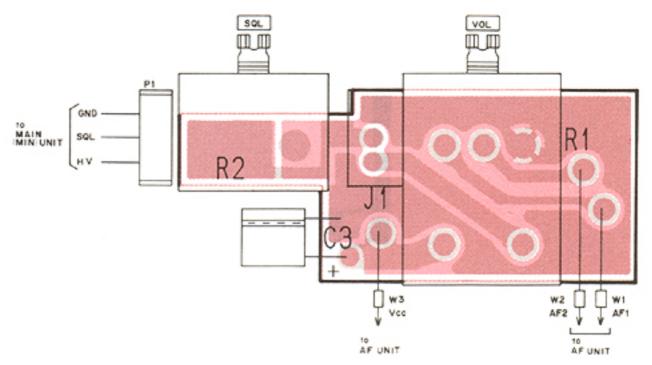
The used parts in the logic daughter units are included in the logic unit parts list.



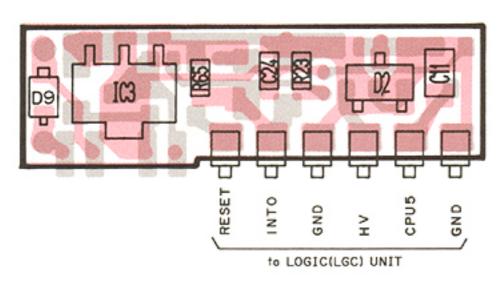


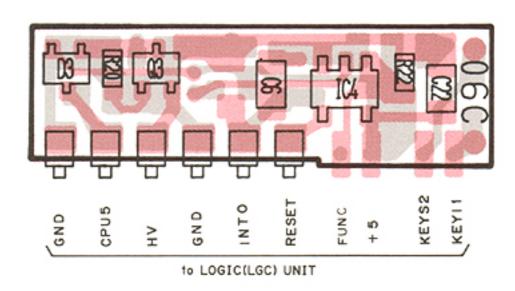
VR UNIT



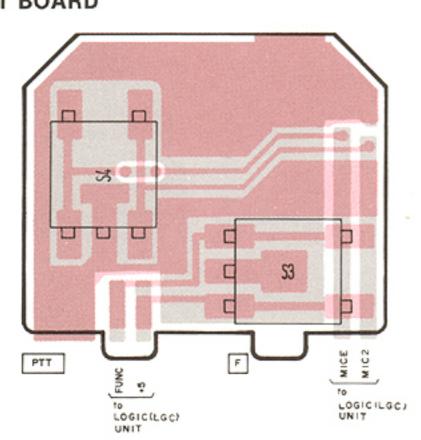


• RES BOARD

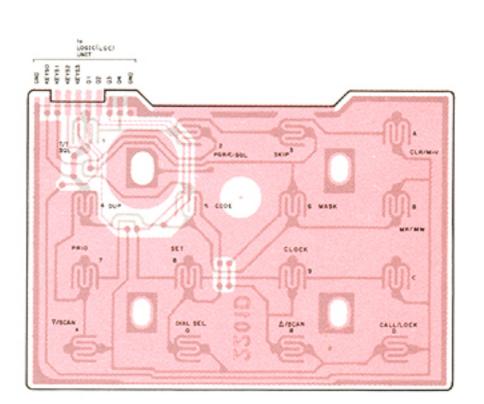




• PTT BOARD



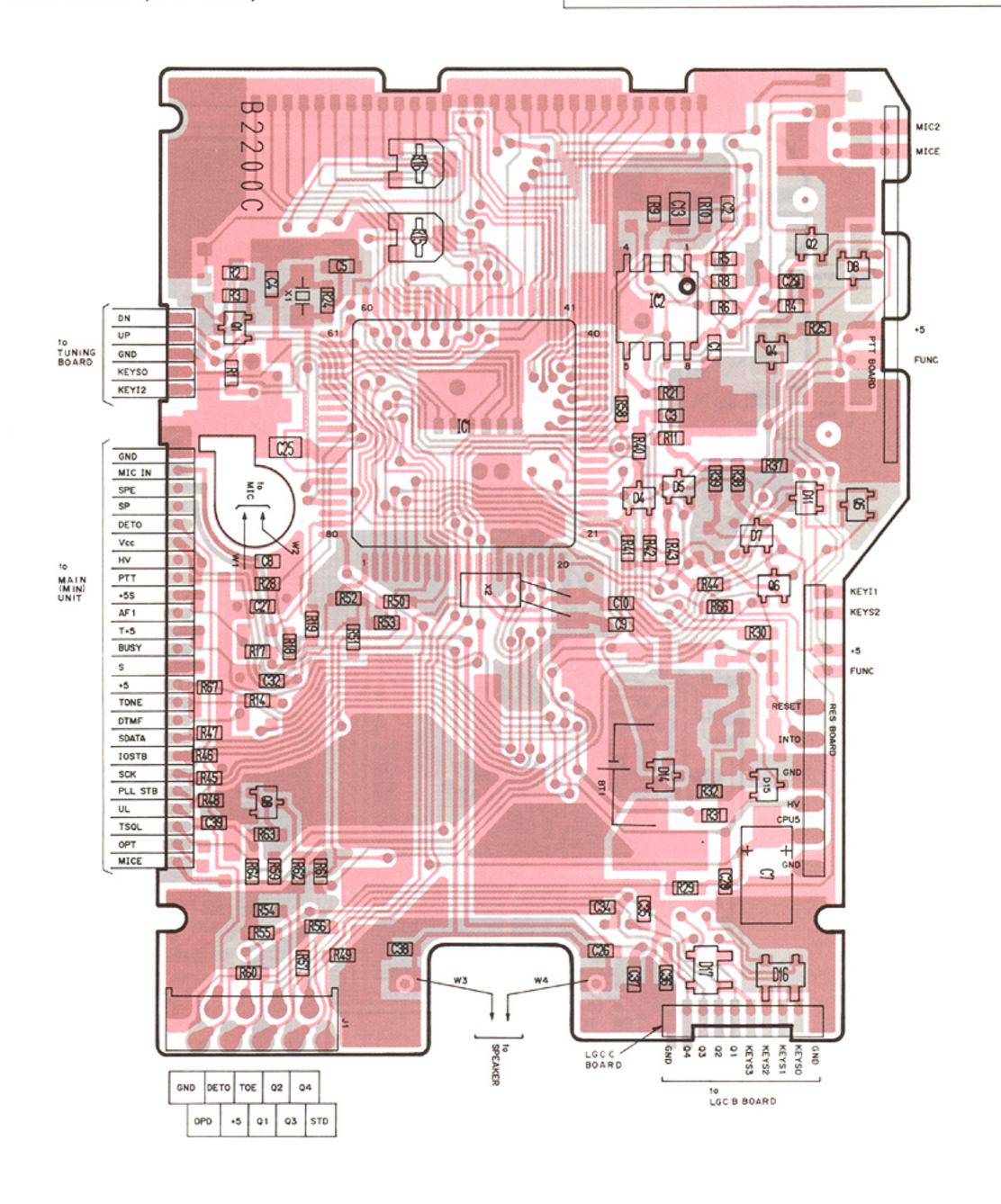
• LGC B BOARD

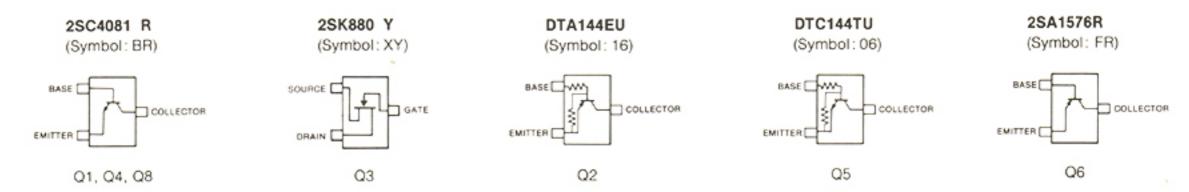


7-2 LOGIC (LGC) UNIT

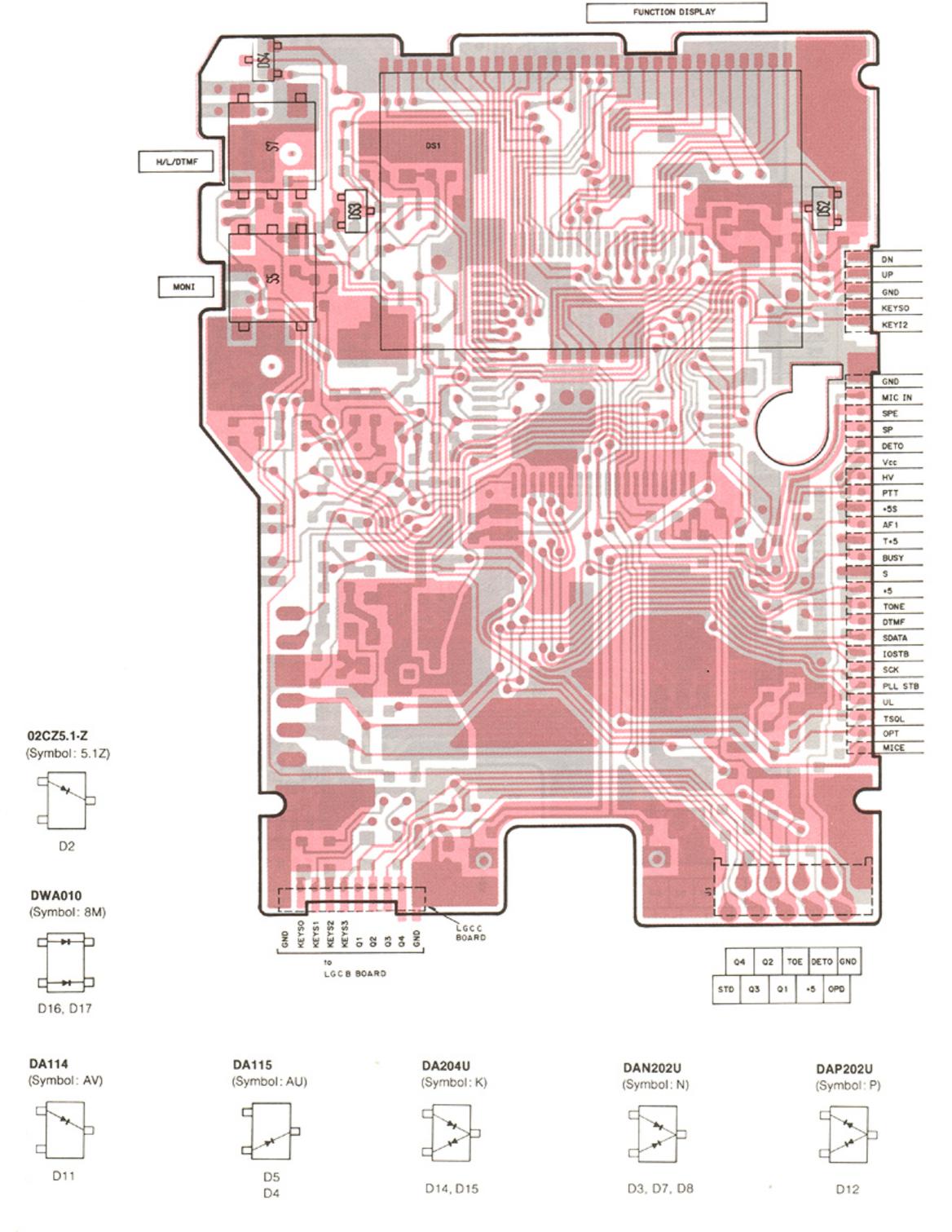
• LOGIC UNIT (TOP VIEW)

The combination of this page and the next page shows the unit layout in the same configuration as the actual P.C. Board.





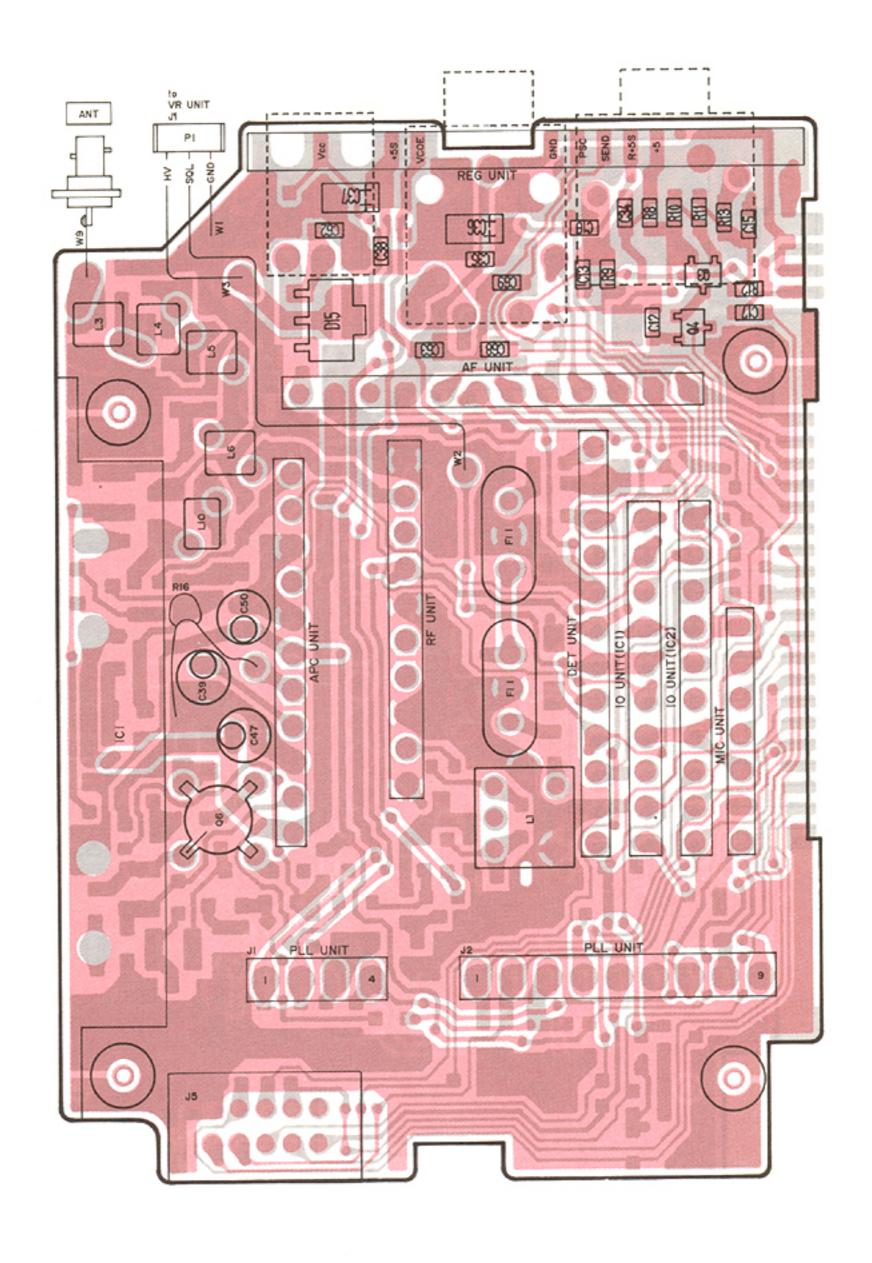
• LOGIC UNIT (BOTTOM VIEW)



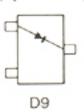
7-3 MAIN UNIT

• MAIN UNIT (TOP VIEW)

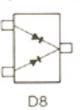
The combination of this page and the next page shows the unit layout in the same configuration as the actual P.C. Board.



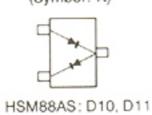




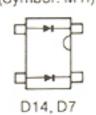
DAN202U (Symbol: N)



HSM88AS (Symbol: C1) DA204U (Symbol: K)



MA862 (Symbol: M1I)



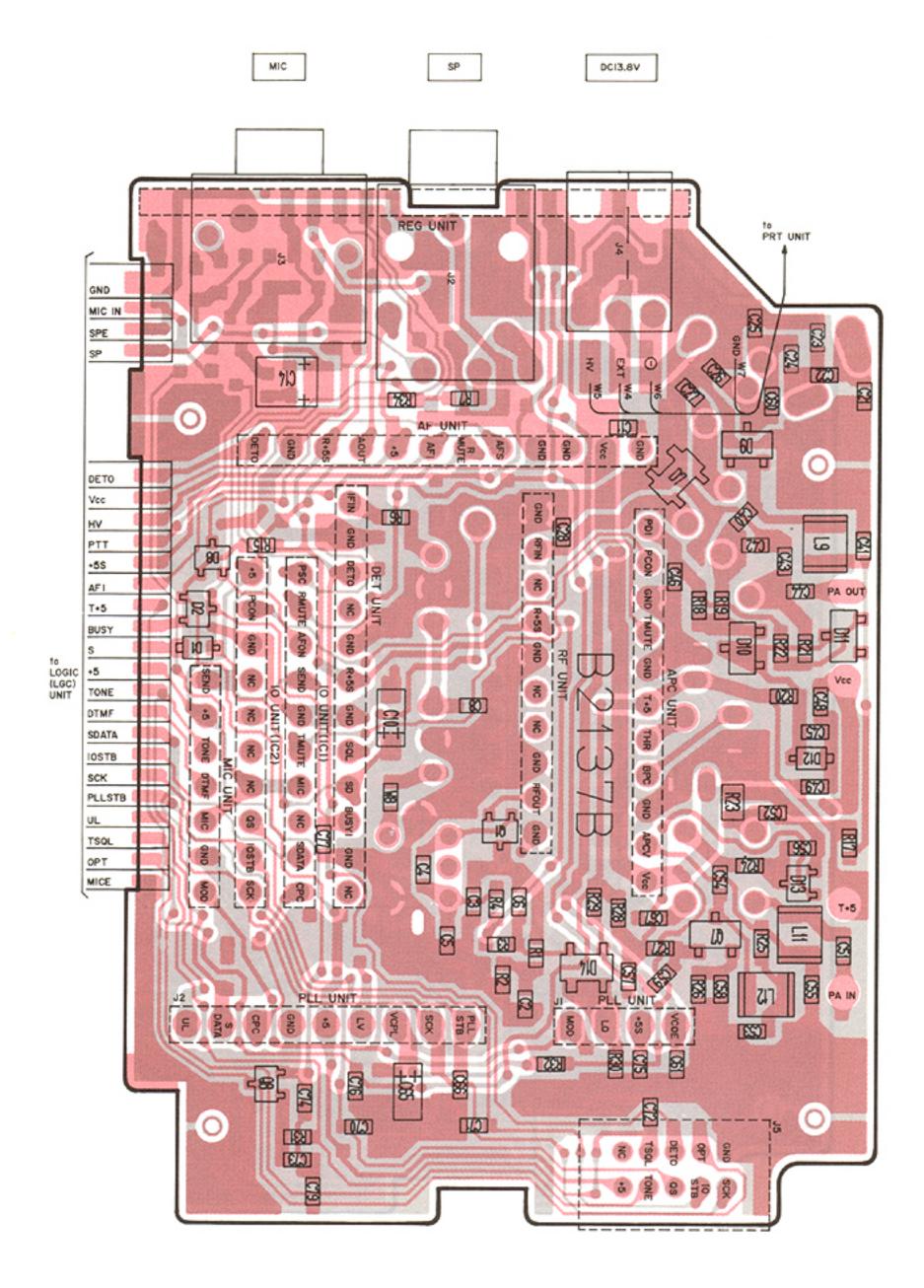
SB20-03P-TD (Symbol: SC)

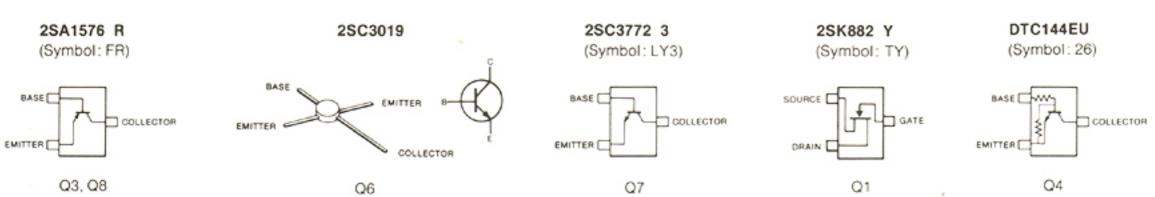


D15

DA204U: D13, D2

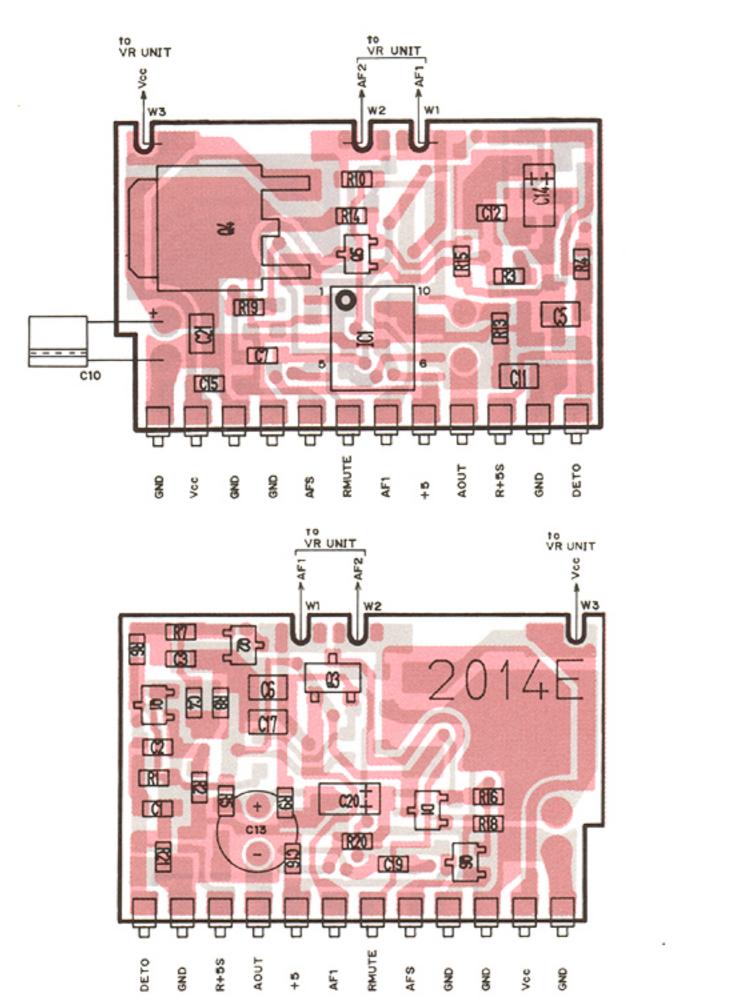
• MAIN UNIT (BOTTOM VIEW)





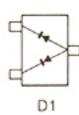
7-4 MAIN DAUGHTER UNITS

AF UNIT

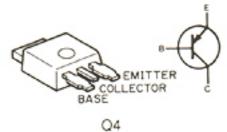


DAP202U

(Symbol: P)

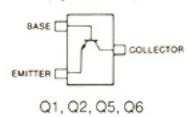


2SB1182 Q



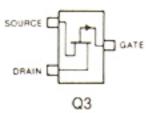
2SC4081 R

(Symbol: BR)

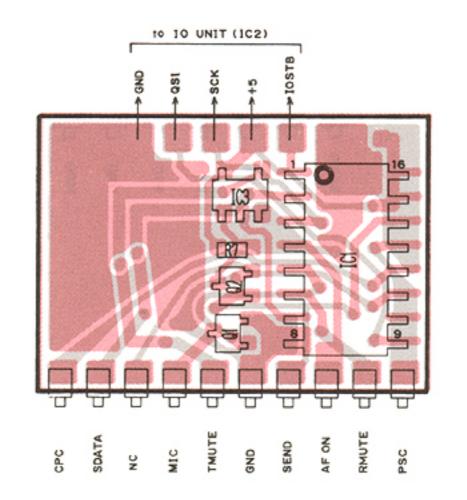


2SJ106-GR

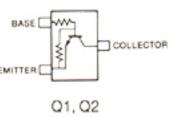
(Symbol: VG)



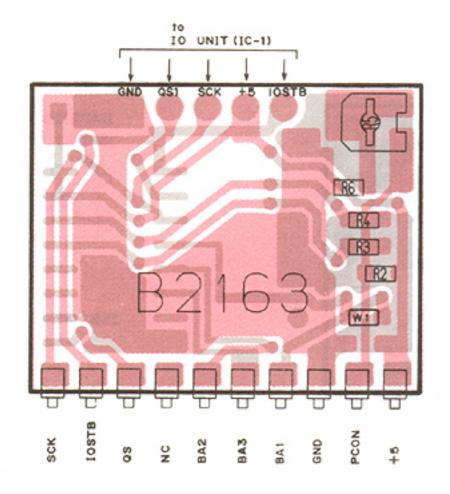
• IO UNIT (IC1)

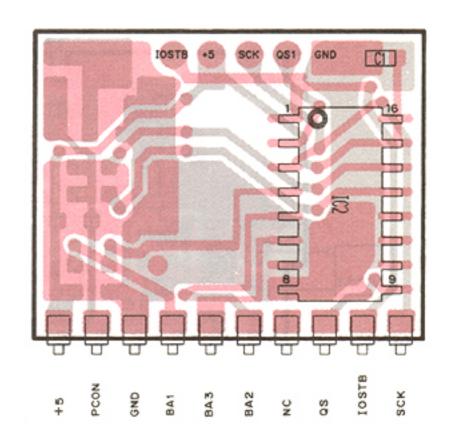


DTC144EU (Symbol: 26)

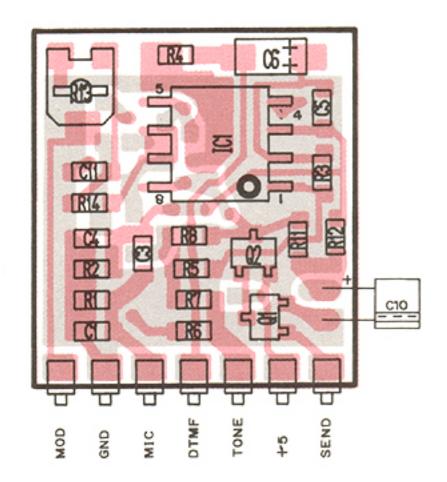


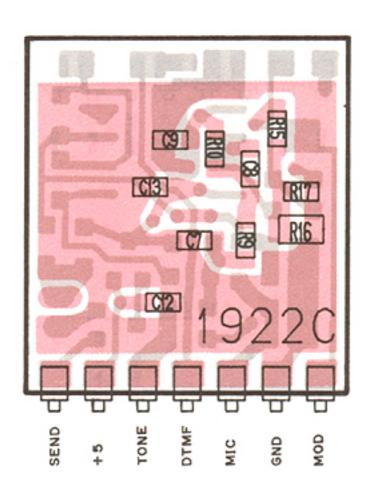
• IO UNIT (IC2)

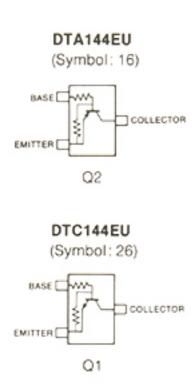




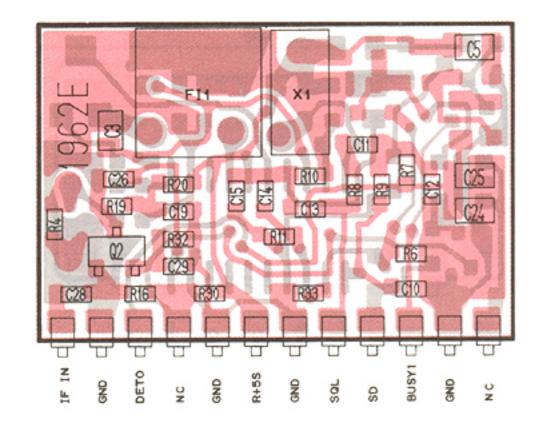
MIC UNIT

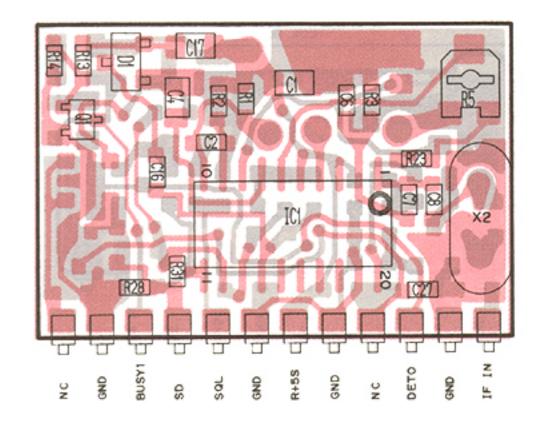






DET UNIT





HSM88AS

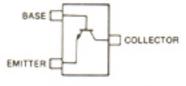
(Symbol: C1)



D1

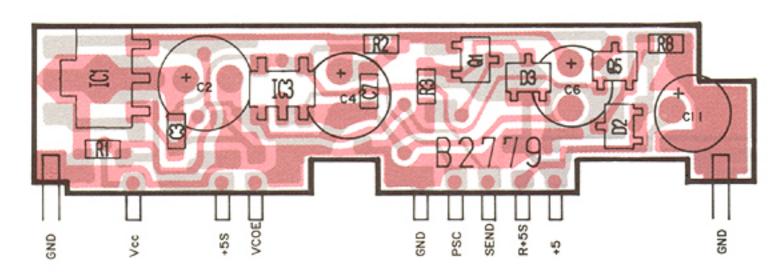
(Symbol: JY3) 2SC4081 S (Symbol: BS)

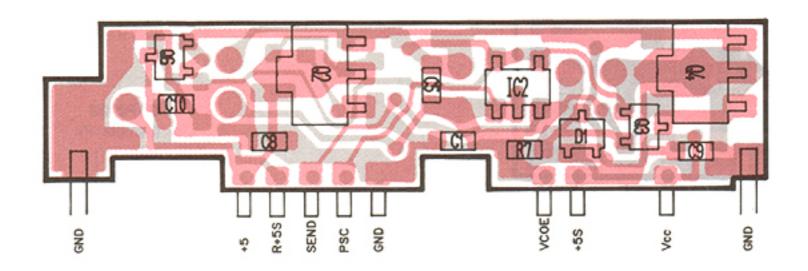
2SC3770 3



2SC37703:Q2 2SC4081 S : Q1

REG UNIT



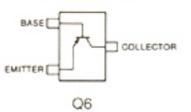




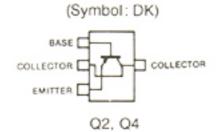


D1, D2, D3

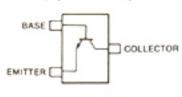
2SA1576 (Symbol: FR)



2SB798

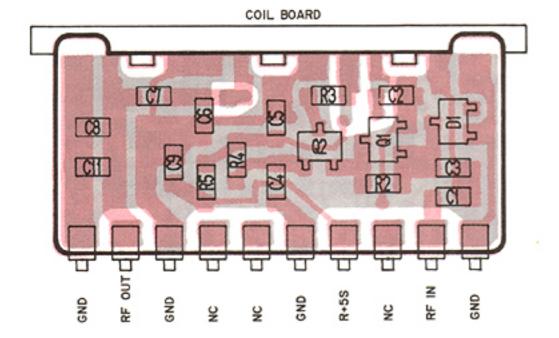


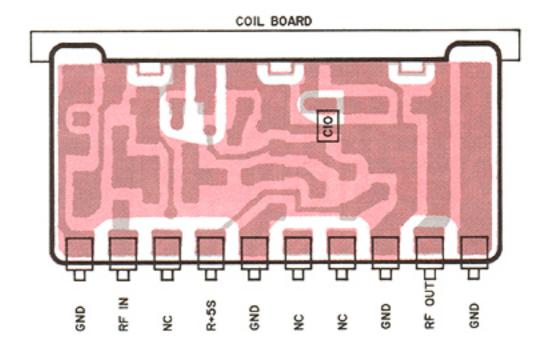
2SC4081 S (Symbol: BS)



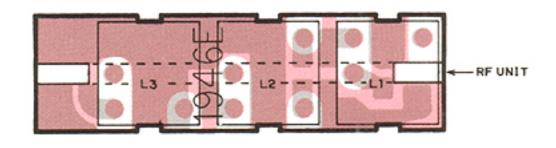
Q1, Q3, Q5

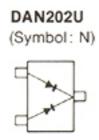
• RF UNIT



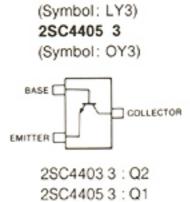


COIL BOARD



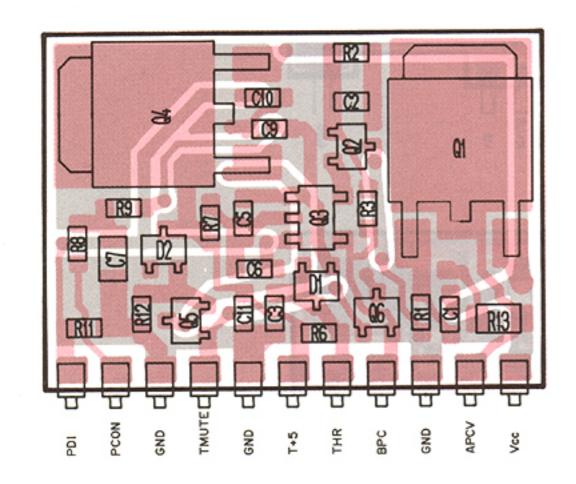


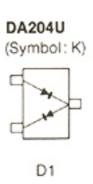
D1

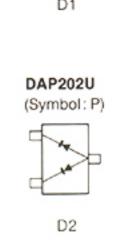


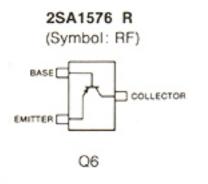
2SC4403 3

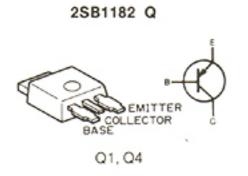
APC UNIT

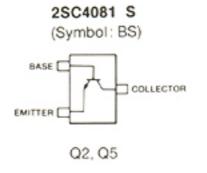


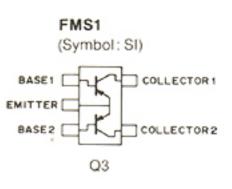




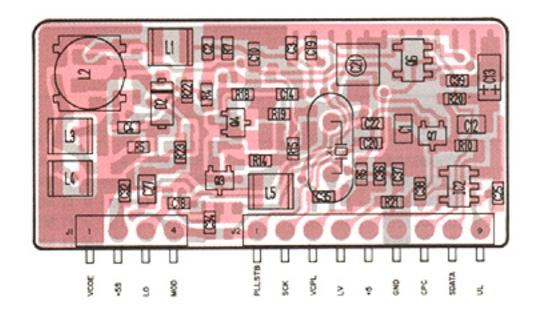


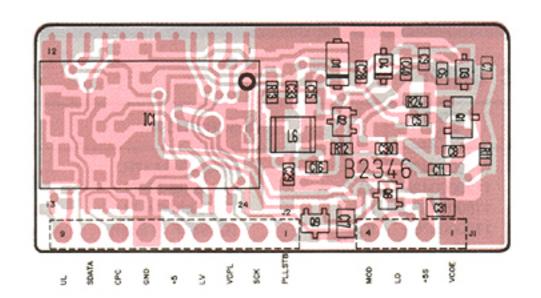


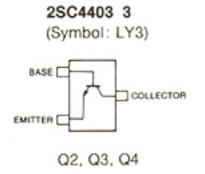


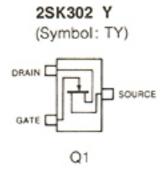


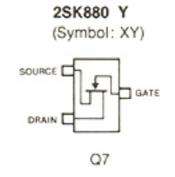
• PLL UNIT

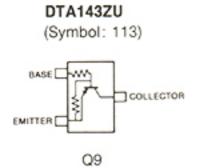


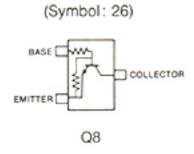




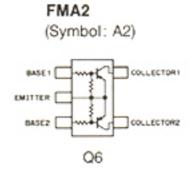




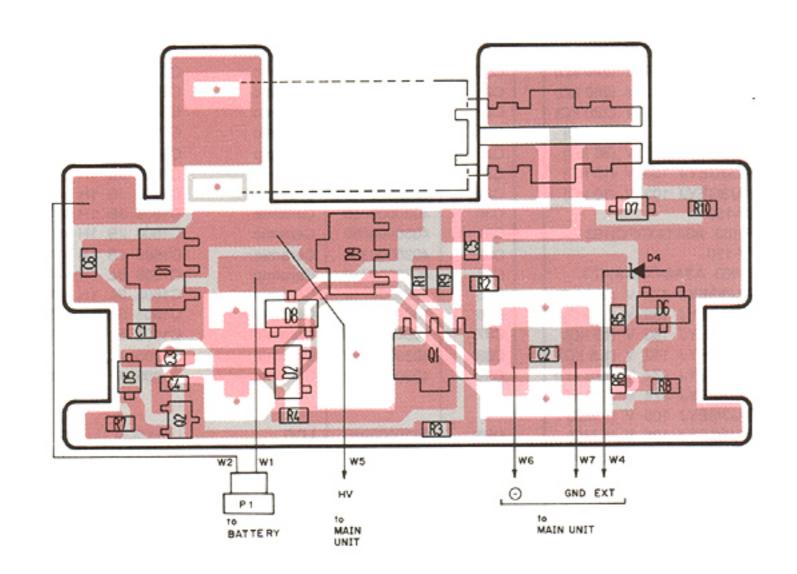




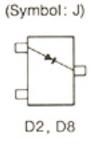
DTC144EU



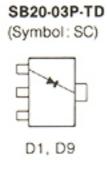
• PRT UNIT

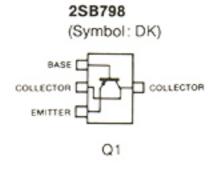


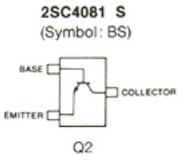
02CZ5.1-Z (Symbol: 5.1Z)



SB07-03C-TA







SECTION 8 PARTS LIST

[LOGIC UNIT]

ORDER REF. DESCRIPTION NO. NO. IC1 1140001420 IC HD404608A47H LA6393M-TP-T1 1120000430 IC IC2 IC3 1180000550 IC RH5VA37CA-T1 IC4 1130003760 TC4S81F (TE85R) 2SC4081 T107 R Q1 1530002060 Transistor Q2 1590000720 Transistor **DTA144EU T107** Q3 1560000540 2SK880-Y (TE85R) FET 2SC4081 T107 R Q4 1530002060 Transistor Q5 1590000660 Transistor DTC144TU T107 06 1510000510 Transistor 2SA1576 T107 B Q8 1530002060 Transistor 2SC4081 T107 R D2 1730002160 Zener 02CZ5.1-Z (TE85R) D3 1160000060 Diode **DAN202U T107** D4 1750000170 Diode **DA115 T107** D5 1750000170 Diode DA115 T107 1160000060 D7 Diode **DAN202U T107** D8 1160000060 Diode **DAN202U T107** D9 1710000600 Diode **1SS254** D11 1750000160 Diode **DA114 T107** 1160000050 D12 Diode **DAP202U T107** D14 1750000130 Diode DA204U T107 D15 1750000130 Diode DA204U T107 1750000120 DWA010-TE D16 Diode 1750000120 DWA010-TE D17 Diode Ceralock 6060000260 CSB800J220 X2 6050005800 Crystal DT-26S 32.768KHZ R1 7030003520 ERJ3GEYJ 472 V (4.7 kΩ) Resistor R2 7030003480 Resistor ERJ3GEYJ 222 V (2.2 kΩ) **B3** 7030003280 Resistor ERJ3GEYJ 470 V (47 Ω) R4 7030003360 FRJ3GEYJ 221 V (220 O) Resistor R5 7030003720 Resistor ERJ3GEYJ 224 V (220 kΩ) R6 7030003880 ERJ3GEYJ 244 V (240 kΩ) Resistor R8 7030003720 ERJ3GEYJ 224 V (220 kΩ) Resistor ERJ3GEYJ 473 V (47 kΩ) 7030003640 RQ Resistor ERJ3GEYJ 563 V (56 kΩ) R10 7030003650 Resistor R11 7030003580 Resistor ERJ3GEYJ 153 V (15 kΩ) R14 7030003560 Resistor ERJ3GEYJ 103 V (10 kΩ) R15 7310002740 **RV-150** Trimmer (RH03 A3A14X0FC)103 R16 7310002600 Trimmer **RV-110** (RH03 A3AS4X0AA)473 R17 7030003760 Resistor ERJ3GEYJ 474 V (470 kΩ) ERJ3GEYJ 153 V (15 kΩ) 7030003580 R18 Resistor 7030003580 ERJ3GEYJ 153 V (15 kΩ) R19 Resistor R20 7030003460 Resistor ERJ3GEYJ 152 V (1.5 kΩ) **R21** 7030003760 Resistor ERJ3GEYJ 474 V (470 kΩ) **R22** 7030003760 Resistor ERJ3GEYJ 474 V (470 kΩ) ERJ3GEYJ 105 V (1 MΩ) R23 7030003800 Resistor 7030003800 R24 Resistor ERJ3GEYJ 105 V (1 MΩ) R25 7030003760 Resistor ERJ3GEYJ 474 V (470 kΩ) R28 7030003620 Resistor ERJ3GEYJ 333 V (33 kΩ) **R29** 7030003380 ERJ3GEYJ 331 V (330 Ω) Resistor ERJ3GEYJ 223 V (22 kΩ) R30 7030003600 Resistor 7030003580 R31 Resistor ERJ3GEYJ 153 V (15 kΩ) R32 7030003610 Resistor ERJ3GEYJ 273 V (27 kΩ) R37 7030003790 Resistor ERJ3GEYJ 824 V (820 kΩ) **R38** 7030003750 Resistor ERJ3GEYJ 394 V (390 kΩ) ERJ3GEYJ 224 V (220 kΩ) R39 7030003720 Resistor ERJ3GEYJ 104 V (100 kΩ) R40 7030003680 Resistor ERJ3GEYJ 473 V (47 kΩ) R41 7030003640 Resistor R42 7030003640 Resistor ERJ3GEYJ 473 V (47 kΩ) R43 7030003640 Resistor ERJ3GEYJ 473 V (47 kΩ)

[LOGIC UNIT]

1	2 0.4111		
REF. NO.	ORDER NO.	[DESCRIPTION
R44	7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)
R45	7030003800	Resistor	ERJ3GEYJ 105 V (1 MΩ)
R46	7030003800	Resistor	ERJ3GEYJ 105 V (1 MΩ)
R47	7030003800	Resistor	ERJ3GEYJ 105 V (1 MΩ)
R48	7030003800	Resistor	ERJ3GEYJ 105 V (1 MΩ)
R49	7030003800	Resistor	ERJ3GEYJ 105 V (1 MΩ)
R50	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)
R51	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)
R52	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)
R53	7030003800	Resistor	ERJ3GEYJ 105 V (1 MΩ)
R54	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ) ERJ3GEYJ 224 V (220 kΩ)
R55	7030003720 7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)
R56	7030003720	Resistor Resistor	ERJ3GEYJ 224 V (220 kΩ)
R58	7030003720	Resistor	ERJ3GEYJ 105 V (1 MΩ)
R59	7030003330	Resistor	ERJ3GEYJ 224 V (220 kΩ)
R60	7030003800	Resistor	ERJ3GEYJ 105 V (1 MΩ)
R61	7030003800	Resistor	ERJ3GEYJ 105 V (1 MΩ)
R62	7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)
R63	7030003800	Resistor	ERJ3GEYJ 105 V (1 MΩ)
R64	7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)
R65	7030003200	Resistor	ERJ3GEYJ 100 V (10 Ω)
R66	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)
R67	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)
C1	4030006860	Ceramic	C1608 JB 1H 102K- T-A
C2	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C3	4030006710	Ceramic	C1608 SL 1H 470J- T-A
C4	4030006800	Ceramic	C1608 SL 1H 221J- T-A C1608 SL 1H 221J- T-A
C5 C6	4030006800 4030004760	Ceramic Ceramic	C2012 JF 1E 104Z- T-A
C7	4550000770	Tantalum	TESVC 0J 226M-12L
C8	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C9	4030000030	Ceramic	C1608 CH 1H 150J- T-A
C10	4030007030	Ceramic	C1608 CH 1H 150J- T-A
C11	4030004760	Ceramic	C2012 JF 1E 104Z- T-A
C13	4030004760	Ceramic	C2012 JF 1E 104Z- T-A
C22	4030004760	Ceramic	C2012 JF 1E 104Z- T-A
C24	4030006860	Ceramic	C1608 JB 1H 102K- T-A
C25	4030004760	Ceramic	C2012 JF 1E 104Z- T-A
C26	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C27	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C28	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C29	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C30 C31	4030006850	Ceramic	C1608 JB 1H 471K- T-A C1608 JB 1H 471K- T-A
C32	4030006850 4030006850	Ceramic Ceramic	C1608 JB 1H 471K- T-A
C34	403000650	Ceramic	C1608 SL 1H 470J- T-A
C35	4030006710	Ceramic	C1608 SL 1H 470J- T-A
C36	4030006710	Ceramic	C1608 SL 1H 470J- T-A
C37	4030006710	Ceramic	C1608 SL 1H 470J- T-A
C38	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C39	4030008430	Ceramic	C1608 JF 1H 223Z- T-A
55.			1.000400
DS1	6910003910	LCD	LCD2439
DS2	5040000950	LED	SLM-13DWS T97B
DS3 DS4	5040000950 5040001110	LED LED	SLM-13DWS T97B SLM-23VMWS T97B
D34	3040001110	LED	OFIM-SOAMIAAO 1910
MC1	7700000860	Microphone	WM-62A
BT1	3020000160	Lithium Battery	VL2020-1VC
	******		000141040
S1	2260000890	Encoder	SRBM1L040A [TUNING]
			(· - · · · · · · · · · · · · · · · · · ·

[LOGIC UNIT]

REF. NO.	ORDER NO.	D	ESCRIPTION
S2	2260001150	Switch	SW-103 (SKHUPC007B)
S3	2230000770	Switch	SW-104 (SKHUPE004B) [F]
S4	2230000770	Switch	SW-104 (SKHUPE004B)
S 5	2260001150	Switch	SW-103 (SKHUPC007B)
S7	2260001150	Switch	SW-103 (SKHUPC007B) [H/L/DTMF]
SP1	2510000450	Speaker	EAS-3P123D
EP1 EP2 EP3 EP4 EP5 EP6 EP7 EP8 EP9 EP10	0910022773 0910024633 0910024674 0910023222 0910021322 0910021912 0910022754 0910023513 6910003110 8930019700	P.C. Board Lead Frame LCD Contact Strip	B 2200C (LOGIC) B 1927C (ENC) B 2106D (RES) B 2276B (PTT) B 2108B B 2111B B 2201D (LGCB) B 2291C HFB2.0-0.7-8 (N) SRCN754

[VR UNIT]

REF. NO.	ORDER NO.	D	ESCRIPTION
R1	7210001440	Variable Resistor	RK097111101NA (10KA) [VOL]
R2	7210001450	Variable Resistor	RK0971110051A (10KB) [SQL]
C1	4030006860 4030006860	Ceramic	C1608 JB 1H 102K- T-A C1608 JB 1H 102K- T-A
C2 C3	4510002650	Ceramic Electrolytic	
EP1	0910024624	P.C. Board	B 1926D
	:	-	

[MAIN UNIT]

[MAIN UNII]				
REF. NO.	ORDER NO.		DESCRIPTION	
IC1	1150000800	IC	SC1107	
Q1 Q3 Q4 Q6 Q7 Q8	1560000550 1510000510 1590000430 153000900 1530002030 1510000510	FET Transistor Transistor Transistor Transistor Transistor	2SK882-Y (TE85R) 2SA1576 T107 R DTC144EU T107 2SC3019 2SC3772-3-TA 2SA1576 T107 R	
D1 D2 D7 D8 D9 D10 D11 D12 D13 D14 D15	1790000590 1750000130 1790000450 1160000060 175000080 1790000490 1790000590 1750000130 1790000450 1790000680	Diode	MA110(TW) DA204U T107 MA862(TX) DAN202U T107 1SS153-T2 HSM88AS-TR HSM88AS-TR MA110(TW) DA204U T107 MA862(TX) SB20-03P-TD	
FI1	2010000230	Filter	30M15B (FL-76)	
L1 L3 L4 L5 L6 L9 L10 L11	6150003210 6110002000 6110002000 6110002000 6110002000 6200000260 6110002040 6200000110 6200000760	Coil Coil Coil Coil Coil Coil Coil Coil	LS-319 LA-226 LA-226 LA-226 LA-226 LQN 2A R10K LA-225 LQN 2A 33NM LQN 2A 56NM	
R1 R2 R3 R4 R6 R7 R8 R9 R10 R11 R12 R13 R15 R16 R17 R18 R19 R20 R21 R22 R23 R24 R25 R26 R27 R28 R29 R30 R31 R32 R34	7030003290 7030003480 7030003400 7030003410 7030003400 7030003400 7030003400 7030003400 7030003400 7030003400 7030003400 7030003400 7030003400 7030003400 7030003400 7030003400 7030003340 7030003550 7030003400 7030003500 7030003200 7030003200 7030003200 7030003410 7030003520 7030003500 7030003500 7030003500 7030003500 7030003500 7030003500 7030003500 7030003500 7030003500 7030003500 7030003500 7030003500 7030003500 7030003500	Resistor	ERJ3GEYJ 560 V (56 Ω) ERJ3GEYJ 222 V (2.2 kΩ) ERJ3GEYJ 472 V (4.7 kΩ) ERJ3GEYJ 471 V (470 Ω) ERJ3GEYJ 561 V (560 Ω) ERJ3GEYJ 474 V (470 kΩ) ERJ3GEYJ 471 V (470 Ω) ERJ3GEYJ 471 V (470 Ω) ERJ3GEYJ 471 V (470 Ω) ERJ3GEYJ 103 V (10 kΩ) ERJ3GEYJ 102 V (1 kΩ) ERJ3GEYJ 103 V (22 kΩ) ERJ3GEYJ 151 V (150 Ω) ERJ3GEYJ 151 V (150 Ω) ERJ3GEYJ 331 V (330 Ω) ERJ3GEYJ 331 V (330 Ω) ERJ3GEYJ 151 V (17 kΩ) ERJ3GEYJ 17 V (100 Ω) ERJ3GEYJ 101 V (100 Ω) ERJ3GEYJ 101 V (100 Ω) ERJ3GEYJ 101 V (100 Ω) ERJ3GEYJ 561 V (560 Ω) ERJ3GEYJ 472 V (4.7 kΩ) ERJ3GEYJ 472 V (4.7 kΩ) ERJ3GEYJ 105 V (1 kΩ) ERJ3GEYJ 105 V (10 kΩ) ERJ3GEYJ 103 V (10 kΩ) ERJ3GEYJ 103 V (10 kΩ)	
C2 C3 C4 C5	4030006860 4030006710 4030006670 4030006860	Ceramic Ceramic Ceramic Ceramic	C1608 JB 1H 102K- T-A C1608 SL 1H 470J- T-A C1608 SL 1H 270J- T-A C1608 JB 1H 102K- T-A	

[MAIN UNIT]

[AF UNIT]

	ORDER NO.		DESCRIPTION	REF. NO.	ORDER NO.		DESCRIPTION
C6	4030006860	Ceramic	C1608 JB 1H 102K- T-A	IC1	1110001810	IC	TA7368F(TP1)
C8	4030006620	Ceramic	C1608 SL 1H 120J- T-A]		
C10	4550000460	Tantalum	TESVA 1C 105M1-8L				
	4030006860	Ceramic	C1608 JB 1H 102K- T-A	Q1	1530002060	Transistor	2SC4081 T107 R
211		l .	C1608 JB 1H 102K- T-A	Q2	1530002060	Transistor	2SC4081 T107 R
212	4030006860	Ceramic		Q3	159000520	FET	2SJ106-GR (TE85R)
C13	4030006860	Ceramic	C1608 JB 1H 102K- T-A	Q4	1520000270	Transistor	2SB1182 T201 Q
C14	4550003040	Tantalum	TEMSVB2 0J 106M-8 L		153000270	Transistor	2SC4081 T107 R
C15	4030006860	Ceramic	C1608 JB 1H 102K- T-A	Q5	1		2SC4081 T107 R
C16	4030006860	Ceramic	C1608 JB 1H 102K- T-A	Q6	1530002060	Transistor	25C4081 1107 H
017	4030006900	Ceramic	C1608 JB 1E 103K- T-A				
C21	4030006620	Ceramic	C1608 SL 1H 120J- T-A		4400000000	Diada	DA B00011 T107
C22	4030006520	Ceramic	C1608 SL 1H 010C- T-A	D1	1160000050	Diode	DAP202U T107
C23	4030006660	Ceramic	C1608 SL 1H 220J- T-A				
C24	4030008440	Ceramic	C1608 SL 1H 1R5C- T-A				
C25	4030006620	Ceramic	C1608 SL 1H 120J- T-A	R1	7030003580	Resistor	ERJ3GEYJ 153 V (15 kΩ)
C26	4030006630	Ceramic	C1608 SL 1H 150J- T-A	R2	7030003700	Resistor	ERJ3GEYJ 154 V (150 kΩ
C27	4030006660	Ceramic	C1608 SL 1H 220J- T-A	R3	7030003760	Resistor	ERJ3GEYJ 474 V (470 kΩ
C28	4030006610	Ceramic	C1608 SL 1H 100D- T-A	R4	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)
C34	4030006860	Ceramic	C1608 JB 1H 102K- T-A	R5	7030003480	Resistor	ERJ3GEYJ 222 V (2.2 kΩ
C35	4030006860	Ceramic	C1608 JB 1H 102K- T-A	R6	7030003630	Resistor	ERJ3GEYJ 393 V (39 kΩ)
	4550002890	Tantalum	TESVA 1A 225M1-8L	R7	7030003630	Resistor	ERJ3GEYJ 393 V (39 kΩ)
C36		Tantalum	TESVA 1A 225M1-8L	R8	7030003480	Resistor	ERJ3GEYJ 222 V (2.2 kΩ
C37	4550002890			R9	7030003480	Resistor	ERJ3GEYJ 105 V (1 MΩ)
C38	4030006860	Ceramic	C1608 JB 1H 102K- T-A		7030003800	1	ERJ3GEYJ 101 V (100 Ω)
C39	4510001380	Electrolytic	25 MS5 4R7 μF	R10		Resistor	
C40	4030006860	Ceramic	C1608 JB 1H 102K- T-A	R13	7030003200	Resistor	ERJ3GEYJ 100 V (10 Ω)
C41	4030006860	Ceramic	C1608 JB 1H 102K- T-A	R14	7030003420	Resistor	ERJ3GEYJ 681 V (680 Ω)
C42	4030006630	Ceramic	C1608 SL 1H 150J- T-A	R15	7030003420	Resistor	ERJ3GEYJ 681 V (680 Ω)
C43	4030006630	Ceramic	C1608 SL 1H 150J- T-A	R16	7030003600	Resistor	ERJ3GEYJ 223 V (22 kΩ)
C44	4030006860	Ceramic	C1608 JB 1H 102K- T-A	R18	7030003760	Resistor	ERJ3GEYJ 474 V (470 kC
C45	4030006860	Ceramic	C1608 JB 1H 102K- T-A	R19	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)
C46	4030006860	Ceramic	C1608 JB 1H 102K- T-A	R20	7030003340	Resistor	ERJ3GEYJ 151 V (150 Ω)
C47	4510003160	Electrolytic	16 RC2 22 μ F (D = 4.0)	R21	7030003520	Resistor	ERJ3GEYJ 472 V (4.7 kΩ)
C48	4030006860	Ceramic	C1608 JB 1H 102K- T-A				
C49	4030006860	Ceramic	C1608 JB 1H 102K- T-A			İ	
C50	4510001350	Electrolytic	16 MS5 10 μF	C1	4030006900	Ceramic	C1608 JB 1E 103K- T-A
C51	4030006590	Ceramic	C1608 SL 1H 080D- T-A	C2	4030006900	Ceramic	C1608 JB 1E 103K- T-A
	1	Ceramic	C1608 JF 1H 103Z- T-A	C3	4030006870	Ceramic	C1608 JB 1H 222K- T-A
C52	4030006890			C4	4030006860	Ceramic	C1608 JB 1H 102K- T-A
C53	4030006860	Ceramic	C1608 JB 1H 102K- T-A		4030004760	Ceramic	C2012 JF 1E 104Z- T-A
C54	4030006610	Ceramic	C1608 SL 1H 100D- T-A	C5		1	C2012 JB 1E 473K- T-A
C55	4030006860	Ceramic	C1608 JB 1H 102K- T-A	C6	4030005110	Ceramic	C1608 JB 1H 102K- T-A
C56	4030006860	Ceramic	C1608 JB 1H 102K- T-A	C7	4030006860	Ceramic	
C57	4030006860	Ceramic	C1608 JB 1H 102K- T-A	C10	4510001340	Electrolytic	10 MS5 33 μF
C58	4030006890	Ceramic	C1608 JF 1H 103Z- T-A	C11	4030005110	Ceramic	C2012 JB 1E 473K- T-A
C59	4030006670	Ceramic	C1608 SL 1H 270J- T-A	C12	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C60	4030006860	Ceramic	C1608 JB 1H 102K- T-A	C13	4510003180	Electrolytic	6.3 RC2 100 μF (D =5.0)
C61	4030006860	Ceramic	C1608 JB 1H 102K- T-A	C14	4550003290	Tantalum	TESVA OG 475M1-8L
C62	4030006860	Ceramic	C1608 JB 1H 102K- T-A	C15	4030006860	Ceramic	C1608 JB 1H 102K- T-A
C63	4030006860	Ceramic	C1608 JB 1H 102K- T-A	C16	4030006860	Ceramic	C1608 JB 1H 102K- T-A
C65	4550000460	Tantalum	TESVA 1C 105M1-8L	C17	4030005110	Ceramic	C2012 JB 1E 473K- T-A
C66	4030006760	Ceramic	C1608 SL 1H 121J- T-A	C19	4030006710	Ceramic	C1608 SL 1H 470J- T-A
C67	4030006860	Ceramic	C1608 JB 1H 102K- T-A	C20	4550002950	Tantalum	TESVA 0J 335M1-8L
C68	4030006860	Ceramic	C1608 JB 1H 102K- T-A	C21	4030004760	Ceramic	C2012 JF 1E 104Z- T-A
	4030006860	Ceramic	C1608 JB 1H 102K- T-A)~ '			
C69	l	Ceramic	C1608 SL 1H 101J- T-A				
C70	4030006750			ED+	0910024656	P.C. Board	B 2014F (AF)
C71	4030006750	Ceramic	C1608 SL 1H 101J- T-A	EP1	6910003110	Lead Frame	HFB2.0-0.7-8 (N)
C72	4030006860	Ceramic	C1608 JB 1H 102K- T-A	EP2	0910003110	Leau i aille	III DE.U-U.I-U (14)
273	4030006860	Ceramic	C1608 JB 1H 102K- T-A	 			
C74	4030006860	Ceramic	C1608 JB 1H 102K- T-A	 			•
C75	4030006750	Ceramic	C1608 SL 1H 101J- T-A				
276	4030006860	Ceramic	C1608 JB 1H 102K- T-A	 			
277	4030006860	Ceramic	C1608 JB 1H 102K- T-A				
C79.	4030006750	Ceramic	C1608 SL 1H 101J- T-A				
		P.C. Board	B 2137B (MAIN)				

[IO UNIT]

IIO OI	,		
REF. NO.	ORDER NO.		DESCRIPTION
IC1	1130000830	IC	μPD4094BG-T1
IC2	1130000830	IC	μPD4094BG-T1
IC3	1130004170	IC	TC4S01F (TE85R)
Q1	1590000430	Transistor	DTC144EU T107
Q2	1590000430	Transistor	DTC144EU T107
R2	7030003700	Resistor	ERJ3GEYJ 154 V (150 kΩ)
R3	7030003680	Resistor	ERJ3GEYJ 104 V (100 kΩ)
R4	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)
R5	7310002580	Trimmer	RV-108
1	777777777		(RH03 A3A15X05A)104
R6	7030003620	Resistor	ERJ3GEYJ 333 V (33 kΩ)
R7	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)
	1000000000	2	C1608 JB 1H 102K- T-A
C1	4030006860	Ceramic	C1600 JB IFT 102K- 1-A
	224222422		5 COTOB (104)
EP1 EP2	0910024663 0910024680	P.C. Board P.C. Board	B 2070D (IC1)
EPZ	0910024000	P.C. Board	B 2163A (IC2)
		ĺ	
	-		
		ĺ	
		i	
		İ	
	1	İ	
		İ	
	-	İ	
		ĺ	

[MIC UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
IC1	1110001540	IC	M5218FP-71A
Q1	1590000430	Transistor	DTC144EU T107
Q2	1590000720	Transistor	DTA144EU T107
R1	7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)
R2	7030003880	Resistor	ERJ3GEYJ 244 V (240 kΩ)
R3	7030003710	Resistor	ERJ3GEYJ 184 V (180 kΩ)
R4	7030003370	Resistor	ERJ3GEYJ 271 V (270 Ω)
R5	7030003670	Resistor	ERJ3GEYJ 823 V (82 kΩ)
R6	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)
R7	7030003680	Resistor	ERJ3GEYJ 104 V (100 kΩ)
R8	7030003740	Resistor	ERJ3GEYJ 334 V (330 kΩ)
R9	7030003630	Resistor	ERJ3GEYJ 393 V (39 kΩ)
R10	7030003630	Resistor	ERJ3GEYJ 393 V (39 kΩ)
R11	7030003440	Resistor	ERJ3GEYJ 102 V (1 kΩ)
R12	7030003710	Resistor	ERJ3GEYJ 184 V (180 kΩ)
R13	7310002600	Trimmer	RV-110
			(RH03 A3AS4X0AA)473
R14	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)
R15	7030003540	Resistor	ERJ3GEYJ 682 V (6.8 kΩ)
R16	7510000180	Thermistor	DTN-T203S223LS(T)
R17	7030003570	Resistor	ERJ3GEYJ 123 V (12 kΩ)
C1	4030006860	Ceramic	C1608 JB 1H 102K- T-A
C3	4030006880	Ceramic	C1608 JB 1H 472K- T-A
C4	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C5	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C6	4550000530	Tantalum	TESVA 1V 104M1-8L
C7	4030008470	Ceramic	C1608 JB 1H 272K- T-A
C8	4030006900	Ceramic	C1608 JB 1E 103K- T-A

[MIC UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
C9	4030006760	1	C1608 SL 1H 121J- T-A
C10	4510001850		16 MS5 4R7 µF
C11	4030006900		C1608 JB 1E 103K- T-A
C12	4030006850		C1608 JB 1H 471K- T-A
C13	4030006850		C1608 JB 1H 471K- T-A
EP1	0910024614	P.C. Board	B 1922D (MIC)
EP2	6910003110	Lead Frame	HFB2.0-0.7-8 (N)

[DET UNIT]

	_		Company of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the contract of the
REF. NO.	ORDER NO.		DESCRIPTION
IC1	1120001650	IC	TK10487MT1
Q1 Q2	1530002280 1530002020	Transistor Transistor	2SC4081 T107 S 2SC3770-3-TA
D1	1790000490	Diode	HSM88AS-TR
FI1	2020000550	Ceramic Filter	CFUM455E
X1 X2	6070000060 6050005010	Discriminator Crystal	CDBM455C7 CR-214
R1 R2 R3 R4 R5 R6 R7 R8 R9 R10 R11 R13 R14 R16 R19 R20 R23 R28 R30 R31 R32 R33	7030003480 7030003440 7030003520 7030003560 7030003560 7030003560 7030003400 703000350 703000370 703000360 703000360 703000360 703000360 7030003400 7030003400 7030003400 7030003400 7030003400 7030003400 7030003400 7030003400 7030003640 7030003640 7030003730	Resistor Resistor Resistor Resistor Trimmer Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor	ERJ3GEYJ 222 V (2.2 kΩ) ERJ3GEYJ 102 V (1 kΩ) ERJ3GEYJ 172 V (4.7 kΩ) ERJ3GEYJ 152 V (1.5 kΩ) RV-109 (RH03 A3AJ3X0BA)222 ERJ3GEYJ 822 V (8.2 kΩ) ERJ3GEYJ 103 V (10 kΩ) ERJ3GEYJ 222 V (2.2 kΩ) ERJ3GEYJ 471 V (470 Ω) ERJ3GEYJ 472 V (4.7 kΩ) ERJ3GEYJ 472 V (4.7 kΩ) ERJ3GEYJ 105 V (1 MΩ) ERJ3GEYJ 105 V (1 MΩ) ERJ3GEYJ 393 V (39 kΩ) ERJ3GEYJ 471 V (470 Ω) ERJ3GEYJ 471 V (470 Ω) ERJ3GEYJ 471 V (470 Ω) ERJ3GEYJ 471 V (470 Ω) ERJ3GEYJ 101 V (100 Ω) ERJ3GEYJ 101 V (100 Ω) ERJ3GEYJ 473 V (47 kΩ) ERJ3GEYJ 473 V (47 kΩ) ERJ3GEYJ 473 V (47 kΩ) ERJ3GEYJ 152 V (1.5 kΩ) ERJ3GEYJ 152 V (1.5 kΩ) ERJ3GEYJ 152 V (1.5 kΩ)
C1 C2 C3 C4 C5 C6 C7	4030004760 4030006740 4030004760 4030004760 4030004760 4030006640 4030006720	Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic	C2012 JF 1E 104Z- T-A C1608 SL 1H 820J- T-A C2012 JF 1E 104Z- T-A C2012 JF 1E 104Z- T-A C2012 JF 1E 104Z- T-A C1608 SL 1H 180J- T-A C1608 SL 1H 560J- T-A

[DET UNIT]

	-		
REF. NO.	ORDER NO.		DESCRIPTION
C8	4030006860	Ceramic	C1608 JB 1H 102K- T-A
C10	4030006860	Ceramic	C1608 JB 1H 102K- T-A
C11	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C12	4030006860	Ceramic	C1608 JB 1H 102K- T-A
C13	4030006860	Ceramic	C1608 JB 1H 102K- T-A
C14	4030006860	Ceramic	C1608 JB 1H 102K- T-A
C15	4030006690	Ceramic	C1608 SL 1H 330J- T-A
C16	4030006860	Ceramic	C1608 JB 1H 102K- T-A
C17	4030004760	Ceramic	C2012 JF 1E 104Z- T-A
C19	4030006890	Ceramic	C1608 JF 1H 103Z- T-A
C24	4030005110	Ceramic	C2012 JB 1E 473K- T-A
C25	4030005110	Ceramic	C2012 JB 1E 473K- T-A
C26	4030006860	Ceramic	C1608 JB 1H 102K- T-A
C27	4030006890	Ceramic	C1608 JF 1H 103Z- T-A
C28	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C29	4030006890	Ceramic	C1608 JF 1H 103Z- T-A
EP1	0910024646	P.C. Board	B 1962F (DET)
EP2	6910003110	Lead Frame	HFB2.0-0.7-8 (N)

[REG UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
IC1	1180000530	lc lc	S-81250HG-RD-T1
IC2	1130004170	IC .	TC4S01F (TE85R)
IC3	1130004170	IC	TC4S01F (TE85R)
Q1	1530002280	Transistor	2SC4081 T107 S
Q2	1520000200	Transistor	2SB798-T2 DK
Q3	1530002280	Transistor	2SC4081 T107 S
Q4	1520000200	Transistor	2SB798-T2 DK
Q5	1530002280	Transistor	2SC4081 T107 S
Q6	1510000510	Transistor	2SA1576 T107 R
D1	1750000160	Diode	DA114 T107
D2	1750000160	Diode	DA114 T107
D3	1750000160	Diode	DA114 T107
R1	7030003400	Resistor	ERJ3GEYJ 471 V (470 Ω)
R2	7030003520	Resistor	ERJ3GEYJ 472 V (4.7 kΩ)
R3 R7	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)
H7 R8	7030003560 7030003560	Resistor Resistor	ERJ3GEYJ 103 V (10 kΩ)
HO	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)
C1	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C2	4510003160	Electrolytic	16 RC2 22 μF (D =4.0)
C3	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C4	4510001320	Electrolytic	6R3 MS5 47 μF
C5	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C6	4510003190	Electrolytic	6.3 RC2 47 µF (D =4.0)
C7	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C8	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C9	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C10	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C11	4510003190	Electrolytic	6.3 RC2 47 μ F (D = 4.0)
			, , , , , , , , , , , , , , , , , , , ,

[REG UNIT]

REF. NO.	ORDER NO.	DESCRIPTION	
EP1	0910024705	P.C. Board	B 2779 (REG)
EP2	6910003110	Lead Frame	HFB2.0-0.7-8 (N)

[RF UNIT]

	_		
REF. NO.	ORDER NO.		DESCRIPTION
Q1	1530002570	Transistor	2SC4405-3-TR
Q2	1530002560	Transistor	2SC4403-3-TR
		ŀ	
l			
D1	1160000060	Diode	DAN202U T107
		ļ	
L1	6150002970	Coil	LS-308
L2	6150002970	Coil	LS-308
L3	6150002970	Coil	LS-308
] _{D0}	700000570	Basistan	ED 120EV L 402 V (40 kO)
R2 R3	7030003570 7030003240	Resistor Resistor	ERJ3GEYJ 123 V (12 kΩ) ERJ3GEYJ 220 V (22 Ω)
R4	7030003240	Resistor	ERJ3GEYJ 123 V (12 kΩ)
R5	7030003370	Resistor	ERJ3GEYJ 271 V (270 Ω)
''	7000000010	110010101	2.10002.10 2.1. 1 (2.70 32)
C1	4030006590	Ceramic	C1608 SL 1H 080D- T-A
C2	4030006590	Ceramic	C1608 SL 1H 080D- T-A
C3	4030006640	Ceramic	C1608 SL 1H 180J- T-A
C4	4030006860	Ceramic	C1608 JB 1H 102K- T-A
C5 C6	4030006860 4030006610	Ceramic Ceramic	C1608 JB 1H 102K- T-A C1608 SL 1H 100D- T-A
C7	4030006510	Ceramic	C1608 SL 1H 1000- 1-A
C8	4030006610	Ceramic .	C1608 SL 1H 100D- T-A
C9	4030006860	Ceramic	C1608 JB 1H 102K- T-A
C10	4030006520	Ceramic	C1608 SL 1H 010C- T-A
C11	4030006520	Ceramic	C1608 SL 1H 010C- T-A
EP1	0910022162	P.C. Board	B 2174B (RF)
EP1	0910022162	P.C. Board	B 1946E (COIL)
EP3	6910003110	Lead Frame	HFB2.0-0.7-8 (N)
	0010000110	2000	(,

[APC UNIT]

REF. NO.	ORDER NO.	DESCRIPTION	
Q1	1520000270	Transistor	2SB1182 T201 Q
Q2	1530002280	Transistor	2SC4081 T107 S
Q3	1590000620	Transistor	FMS1 T148
Q4	1520000270	Transistor	2SB1182 T201 Q

[APC UNIT]

REF.	ORDER NO.		DESCRIPTION
Q5	1530002280	Transistor	2SC4081 T107 S
Q6	1510000510	Transistor	2SA1576 T107 R
D1 D2	1750000130 1160000050	Diode Diode	DA204U T107 DAP202U T107
R1	7030003520	Resistor	ERJ3GEYJ 472 V (4.7 kΩ)
R2	7030003770	Resistor	ERJ3GEYJ 564 V (560 kΩ)
R3	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)
R6 R7	7030003600 7030003670	Resistor Resistor	ERJ3GEYJ 223 V (22 kΩ) ERJ3GEYJ 823 V (82 kΩ)
R8	7030003440	Resistor	ERJ3GEYJ 102 V (1 kΩ)
R9	7030003440	Resistor	ERJ3GEYJ 102 V (1 kΩ)
R11	7030003440	Resistor	ERJ3GEYJ 223 V (22 kΩ)
R12	7030003480	Resistor	ERJ3GEYJ 222 V (2.2 kΩ)
R13	7030003400	Resistor	MCR10EZHJ 3.3 kΩ (332)
11113	7000000440	ricolator	MOTTOLETTO C.O REZ (COE)
C1	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C2	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C3	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C5	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C6	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C7	4030004760	Ceramic	C2012 JF 1E 104Z- T-A
C9	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C10	4030006850	Ceramic	C1608 JB 1H 471K- T-A
C11	4030006850	Ceramic	C1608 JB 1H 471K- T-A
EP1	0910024691	P.C. Board	B 2361A (APC)
EP2	6910003110	Lead Frame	HFB2.0-0.7-8 (N)

[PLL UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
IC1	1120001550	IC	M54959FP
IC2	1130004200	IC	TC4S66F (TE85R)
Q1	1560000270	FET	2SK302-Y (TE85R)
Q2	1530002560	Transistor	2SC4403-3-TR
Q3	1530002560	Transistor	2SC4403-3-TR
Q4	1530002560	Transistor	2SC4403-3-TR
Q6	1590000970	Transistor	FMA2 T148
Q7	1560000540	FET	2SK880-Y (TE85R)
Q8	1590000430	Transistor	DTC144EU T107
Q9	1590000440	Transistor	DTA143ZU T107
D1	1790000460	Varicap	MA334B(TX)
D2	1790000530	Varicap	MA333(TW)
D3	1790000620	Diode	MA77(TW)
D4	1790000640	Varicap	MA363B(TX)
X1	6050005790	Crystal	CR-257
L1	6200000240	Coil	LQH 3N R68M
L2	6130002000	Coil	LB-204
L3	6200000750	Coil	LQH 3N 4R7M
L4	6200000750	Coil	LQH 3N 4R7M

[PLL UNIT]

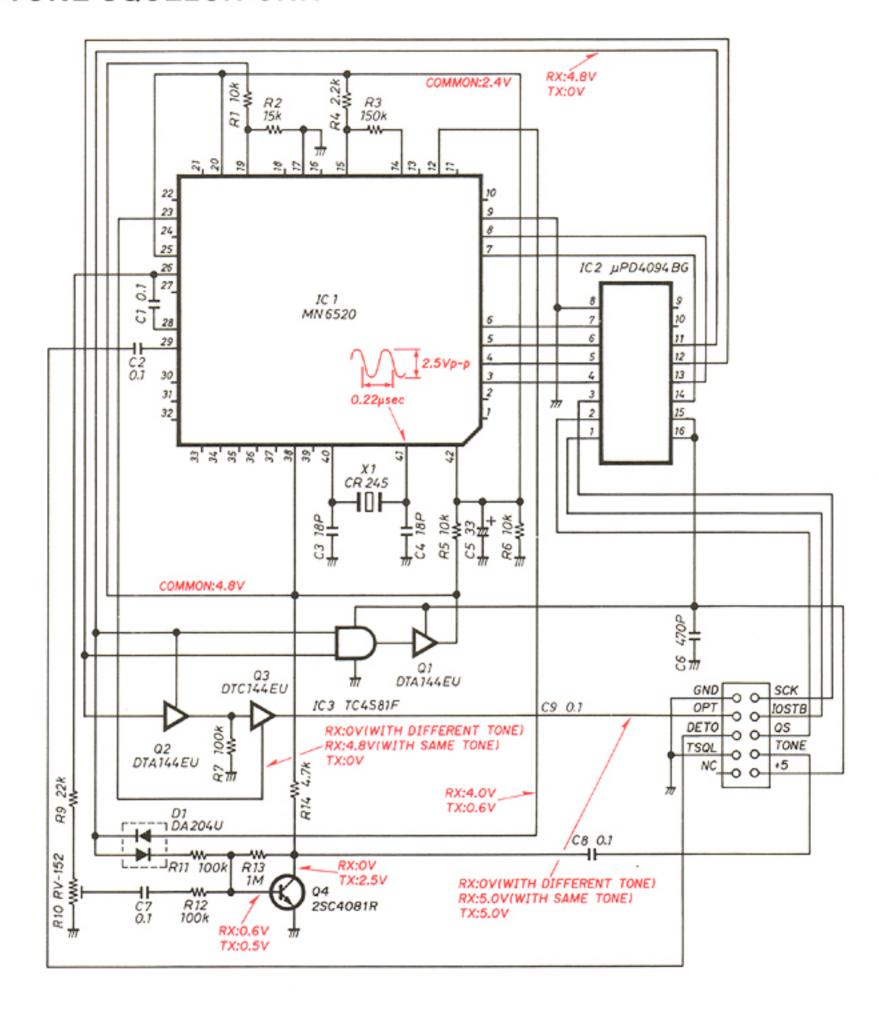
[PLL UNIT]				
REF. NO.	ORDER NO.		DESCRIPTION	
L5	6200000910	Coil	LQN 2A 82NM	
L6	6200000910	Coil	LQN 2A 82NM	
		doment		
R4	7030003440	Resistor	ERJ3GEYJ 102 V (1 kΩ) ERJ3GEYJ 822 V (8.2 kΩ)	
R5 R6	7030003550	Resistor Resistor	ERJ3GEYJ 103 V (10 kΩ)	
R7	7030003800	Resistor	ERJ3GEYJ 105 V (1 MΩ)	
R10 R11	7030003550	Resistor Resistor	ERJ3GEYJ 822 V (8.2 kΩ) ERJ3GEYJ 220 V (22 Ω)	
R12	7030003240	Resistor	ERJ3GEYJ 683 V (68 kΩ)	
R13	7030003420	Resistor	ERJ3GEYJ 681 V (680 Ω)	
R14 R15	7030003650 7030003390	Resistor Resistor	ERJ3GEYJ 563 V (56 kΩ) ERJ3GEYJ 391 V (390 Ω)	
R18	7030003680	Resistor	ERJ3GEYJ 104 V (100 kΩ)	
R19	7030003400	Resistor	ERJ3GEYJ 471 V (470 Ω)	
R20 R21	7030003500	Resistor Resistor	ERJ3GEYJ 332 V (3.3 kΩ) ERJ3GEYJ 105 V (1 MΩ)	
R22	7030003680	Resistor	ERJ3GEYJ 104 V (100 kΩ)	
R23	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ) ERJ3GEYJ 104 V (100 kΩ)	
R24	7030003680	Resistor	ENJ3GETJ 104 V (100 K12)	
	400000 1700	0	C0040 IF 45 4047 T 4	
C1 C2	4030004760 4030006900	Ceramic Ceramic	C2012 JF 1E 104Z- T-A C1608 JB 1E 103K- T-A	
C3	4030006860	Ceramic	C1608 JB 1H 102K- T-A	
C4	4030006670	Ceramic	C1608 SL 1H 270J- T-A	
C5 C6	4030006690 4030006710	Ceramic Ceramic	C1608 SL 1H 330J- T-A C1608 SL 1H 470J- T-A	
C7	4030006540	Ceramic	C1608 SL 1H 030C- T-A	
C8	4030006560 4030006860	Ceramic	C1608 SL 1H 050C- T-A C1608 JB 1H 102K- T-A	
C9 C10	4030006860	Ceramic Ceramic	C1608 JB 1H 102K- T-A	
C11	4030008440	Ceramic	C1608 SL 1H 1R5C- T-A	
C12 C13	4030004760 4550000460	Ceramic Tantalum	C2012 JF 1E 104Z- T-A TESVA 1C 105M1-8L	
C14	4030006620	Ceramic	C1608 SL 1H 120J- T-A	
C15	4030006560	Ceramic	C1608 SL 1H 050C- T-A	
C16 C17	4030006560 4030004760	Ceramic Ceramic	C1608 SL 1H 050C- T-A C2012 JF 1E 104Z- T-A	
C18	4030006610	Ceramic	C1608 SL 1H 100D- T-A	
C19 C20	4030006860 4030007080	Ceramic Ceramic	C1608 JB 1H 102K- T-A C1608 CH 1H 390J- T-A	
C21	4610001260	Trimmer	ECRJA020E12W	
C22	4030007030	Ceramic	C1608 CH 1H 150J- T-A	
C25 C27	4030006850 4030004760	Ceramic Ceramic	C1608 JB 1H 471K- T-A C2012 JF 1E 104Z- T-A	
C28	4030006530	Ceramic	C1608 SL 1H 020C- T-A	
C29	4030006860	Ceramic	C1608 JB 1H 102K- T-A	
C30 C31	4030006560 4030004760	Ceramic Ceramic	C1608 SL 1H 050C- T-A C2012 JF 1E 104Z- T-A	
C32	4030006860	Ceramic	C1608 JB 1H 102K- T-A	
C33 C34	4030006860 4030006750	Ceramic Ceramic	C1608 JB 1H 102K- T-A C1608 SL 1H 101J- T-A	
C35	4030006750	Ceramic	C1608 SL 1H 101J- T-A	
C36	4030006860	Ceramic	C1608 JB 1H 102K- T-A	
C37 C38	4030006750 4030006860	Ceramic Ceramic	C1608 SL 1H 101J- T-A C1608 JB 1H 102K- T-A	
C39	4030006750	Ceramic	C1608 SL 1H 101J- T-A	
C40	4030006580	Ceramic	C1608 SL 1H 070D- T-A	
EP1	0910024411	P.C. Board	B 2346A (PLL)	

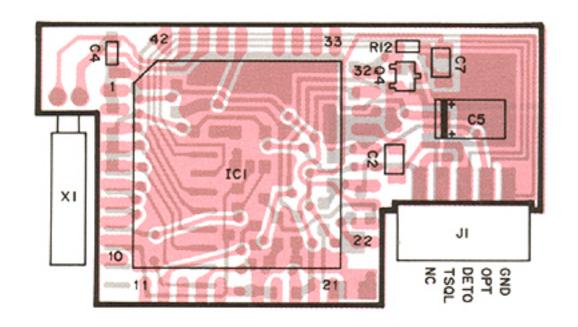
[PRT UNIT]

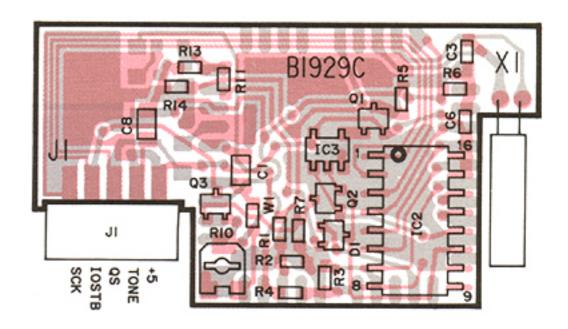
R2 7030003380 Resistor ERJ3GEYJ 331 V (330 G) R3 7030003440 Resistor ERJ3GEYJ 102 V (1 kΩ) R4 7030003600 Resistor ERJ3GEYJ 223 V (22 kΩ R5 7030003470 Resistor ERJ3GEYJ 182 V (1.8 kΩ R6 7030003520 Resistor ERJ3GEYJ 472 V (4.7 kΩ R7 703000320 Resistor ERJ3GEYJ 101 V (100 Ω R8 7030003250 Resistor ERJ3GEYJ 102 V (1 kΩ R9 7030003250 Resistor ERJ3GEYJ 102 V (27 Ω R10 7030003230 Resistor ERJ3GEYJ 180 V (18 Ω C1 4030006860 Ceramic C1608 JB 1H 102K- T-A C2 4030006860 Ceramic C1608 JB 1H 102K- T-A C3 4030006860 Ceramic C1608 JB 1H 102K- T-A C4 4030006860 Ceramic C1608 JB 1H 102K- T-A	PRI UNII;				
Q2 1530002280 Transistor 2SC4081 T107 S D1 1790000680 Diode SB20-03P-TD D2 1790000670 Diode SB07-03C-TA D5 1790000590 Diode MA110(TW) D6 1730002160 Zener 02C25.1-Z (TE85R) D7 1790000590 Diode MA110(TW) D8 1790000670 Diode SB07-03C-TA D9 1790000680 Diode SB20-03P-TD R1 7030003350 Resistor ERJ3GEYJ 270 V (27 Ω R2 7030003380 Resistor ERJ3GEYJ 331 V (330 Ω R3 7030003440 Resistor ERJ3GEYJ 331 V (330 Ω R4 7030003400 Resistor ERJ3GEYJ 102 V (1 kΩ R6 7030003400 Resistor ERJ3GEYJ 223 V (22 kΩ R7 7030003520 Resistor ERJ3GEYJ 472 V (4.7 kΩ R8 703000320 Resistor ERJ3GEYJ 101 V (100 Ω R8 7030003250 Resistor ERJ3GEYJ 102 V (1 kΩ R9			DESCRIPTION		
D2		1			
R2 7030003380 Resistor ERJ3GEYJ 331 V (330 G) R3 7030003440 Resistor ERJ3GEYJ 102 V (1 kΩ) R4 7030003600 Resistor ERJ3GEYJ 223 V (22 kΩ R5 7030003470 Resistor ERJ3GEYJ 182 V (1.8 kΩ R6 7030003520 Resistor ERJ3GEYJ 101 V (100 Ω R8 7030003440 Resistor ERJ3GEYJ 101 V (100 Ω R9 7030003250 Resistor ERJ3GEYJ 102 V (1 kΩ) R10 7030003230 Resistor ERJ3GEYJ 270 V (27 Ω R10 7030003230 Resistor ERJ3GEYJ 180 V (18 Ω) C1 4030006860 Ceramic C1608 JB 1H 102K- T-A C2 4030006860 Ceramic C1608 SL 1H 470J- T-A C3 4030006860 Ceramic C1608 JB 1H 102K- T-A C5 4030006860 Ceramic C1608 JB 1H 102K- T-A C6 4030006860 Ceramic C1608 JB 1H 102K- T-A	179000670 1790000590 1730002160 1790000590 1790000670	Diode Diode Zener Diode Diode	SB07-03C-TA MA110(TW) 02CZ5.1-Z (TE85R) MA110(TW) SB07-03C-TA		
C2 4030006860 Ceramic C1608 JB 1H 102K- T-A C3 4030006710 Ceramic C1608 SL 1H 470J- T-A C4 4030006860 Ceramic C1608 JB 1H 102K- T-A C5 4030006860 Ceramic C1608 JB 1H 102K- T-A C6 4030006860 Ceramic C1608 JB 1H 102K- T-A	7030003380 7030003440 7030003600 7030003470 7030003520 7030003320 7030003440 7030003250	Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor Resistor	ERJ3GEYJ 270 V (27 Ω) ERJ3GEYJ 331 V (330 Ω) ERJ3GEYJ 102 V (1 kΩ) ERJ3GEYJ 223 V (22 kΩ) ERJ3GEYJ 182 V (1.8 kΩ) ERJ3GEYJ 472 V (4.7 kΩ) ERJ3GEYJ 101 V (100 Ω) ERJ3GEYJ 102 V (1 kΩ) ERJ3GEYJ 270 V (27 Ω) ERJ3GEYJ 180 V (18 Ω)		
EP1 0910023862 P.C. Board B 2278B (PRT)	4030006860 4030006710 4030006860 4030006860	Ceramic Ceramic Ceramic Ceramic	C1608 JB 1H 102K- T-A C1608 JB 1H 102K- T-A C1608 SL 1H 470J- T-A C1608 JB 1H 102K- T-A C1608 JB 1H 102K- T-A C1608 JB 1H 102K- T-A		
	0910023862	P.C. Board	B 2278B (PRT)		
		NO. 1520000200 1530002280 1790000680 1790000670 1790000590 1730002160 1790000670 1790000680 7030003250 7030003440 703000340 7030003520 703000340 7030003520 7030003250 7030003250 7030003250 7030003250 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860	NO. 1520000200 Transistor 1530002280 Transistor 1790000680 Diode 1790000590 Diode 1790000590 Diode 1790000590 Diode 1790000670 Diode 1790000680 Diode 7030003250 Resistor 7030003380 Resistor 7030003440 Resistor 7030003520 Resistor 7030003520 Resistor 7030003470 Resistor 7030003520 Resistor 703000320 Resistor 703000320 Resistor Resistor Resistor 703000320 Resistor Resistor Resistor Resistor Resistor 7030003250 Resistor Resistor Resistor Ceramic Ceramic 4030006860 Ceramic 4030006860 Ceramic 4030006860 Ceramic 4030006860 Ceramic		

SECTION 9 OPTIONAL UNITS

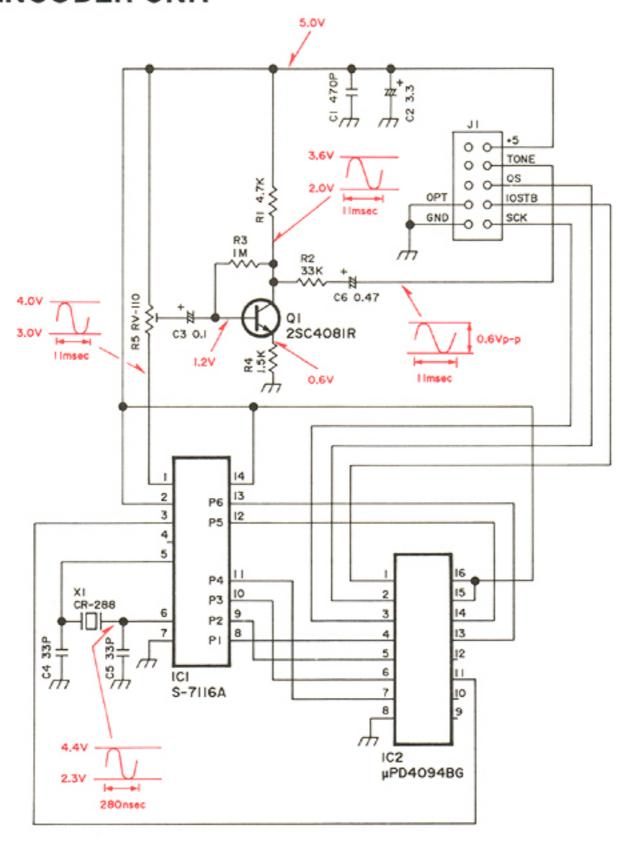
9-1 UT-50 TONE SQUELCH UNIT

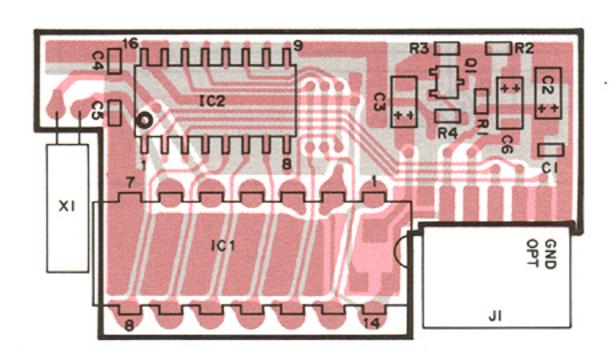


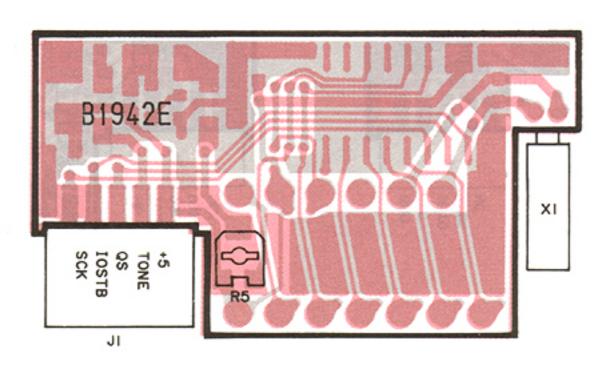




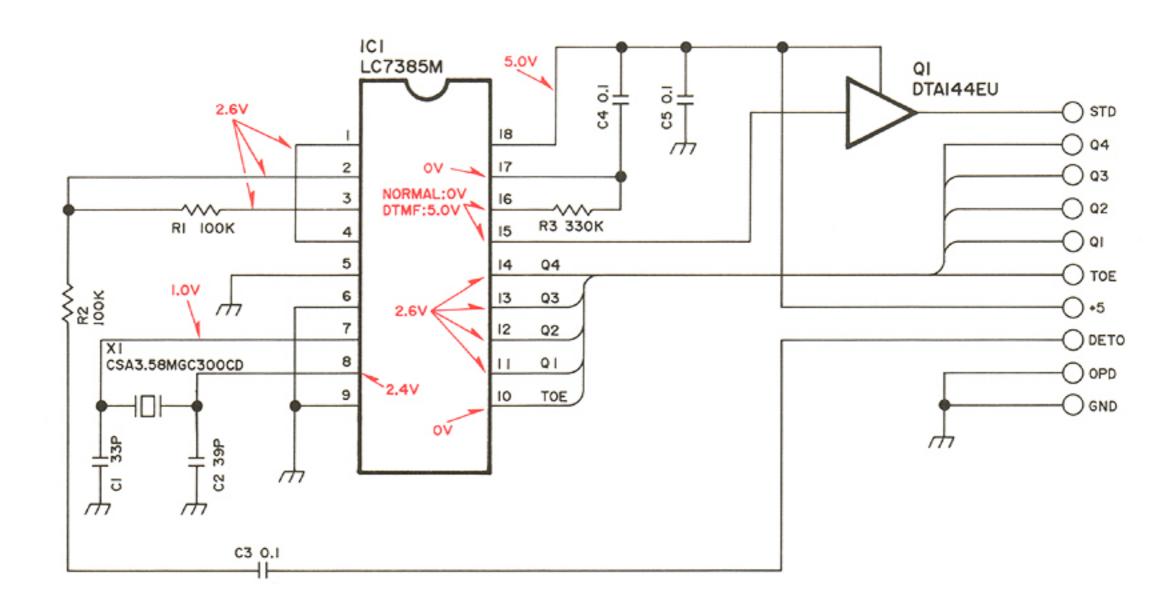
9-2 UT-51 TONE ENCODER UNIT

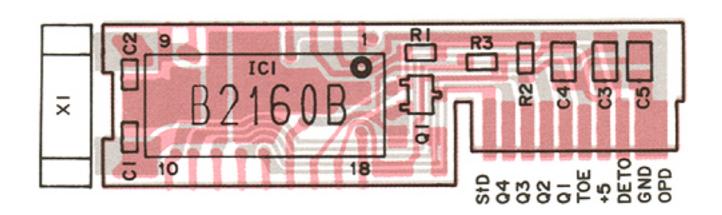




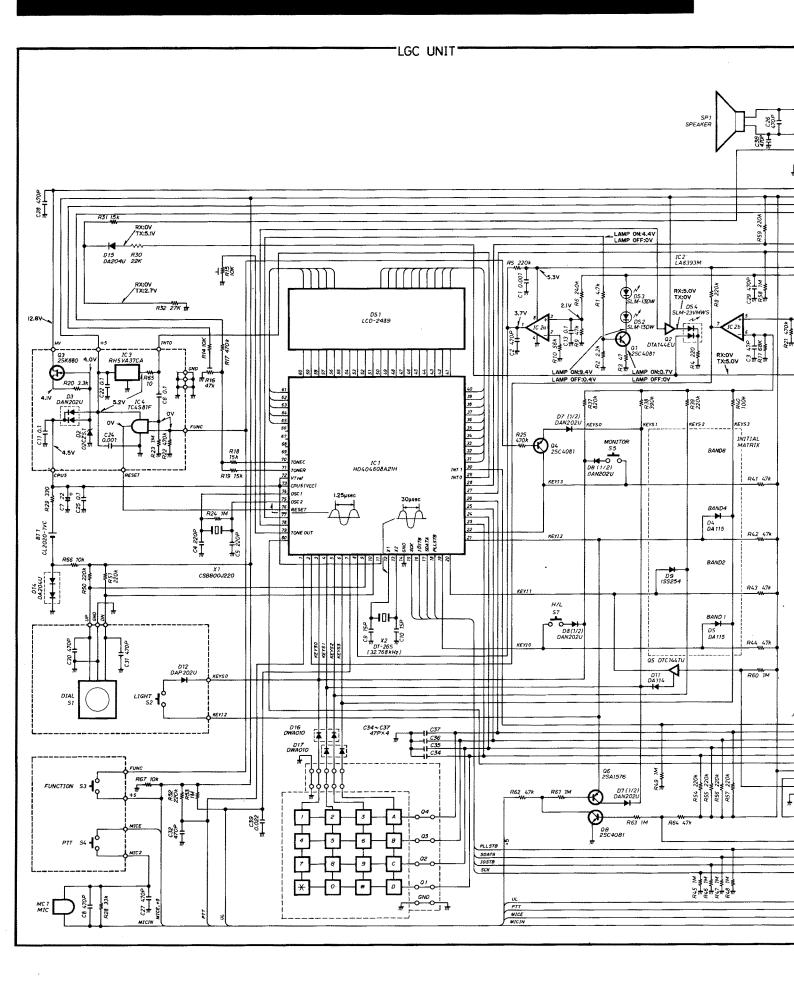


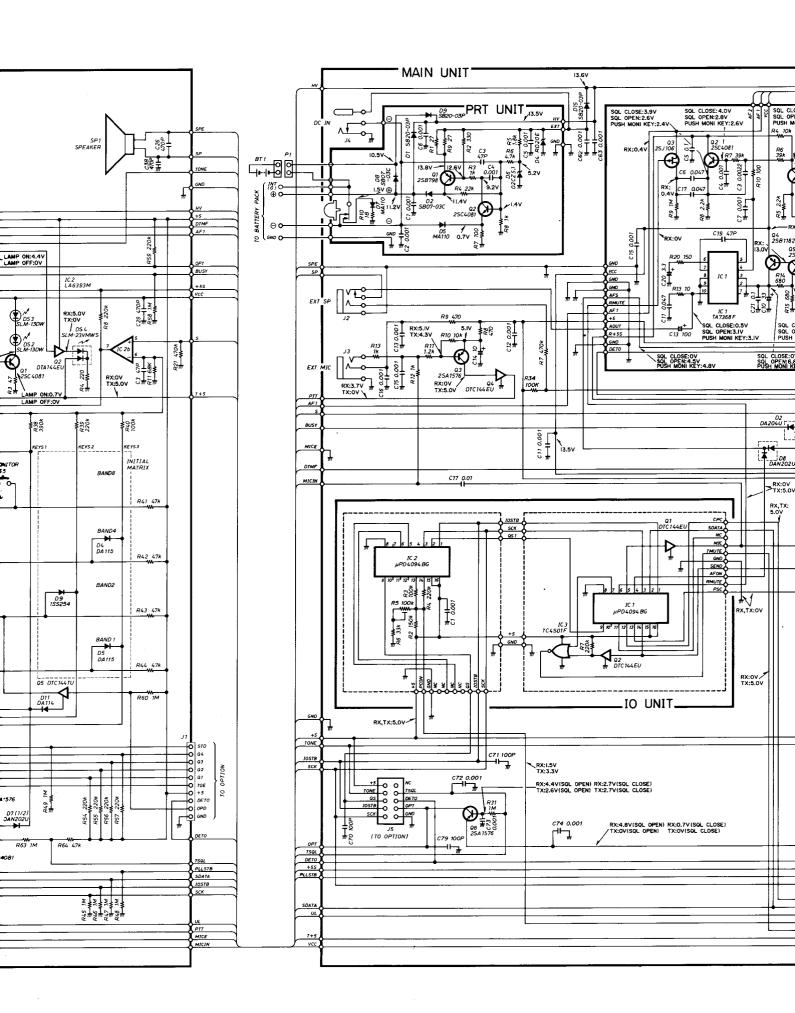
9-3 UT-49 DTMF DECODER UNIT

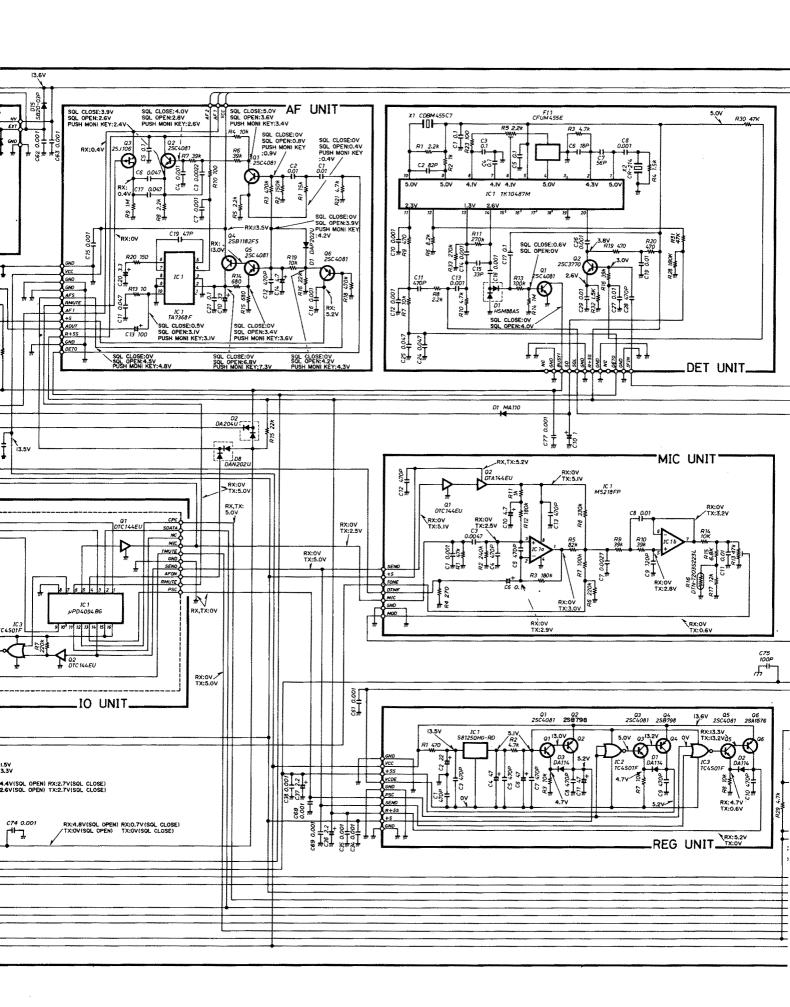


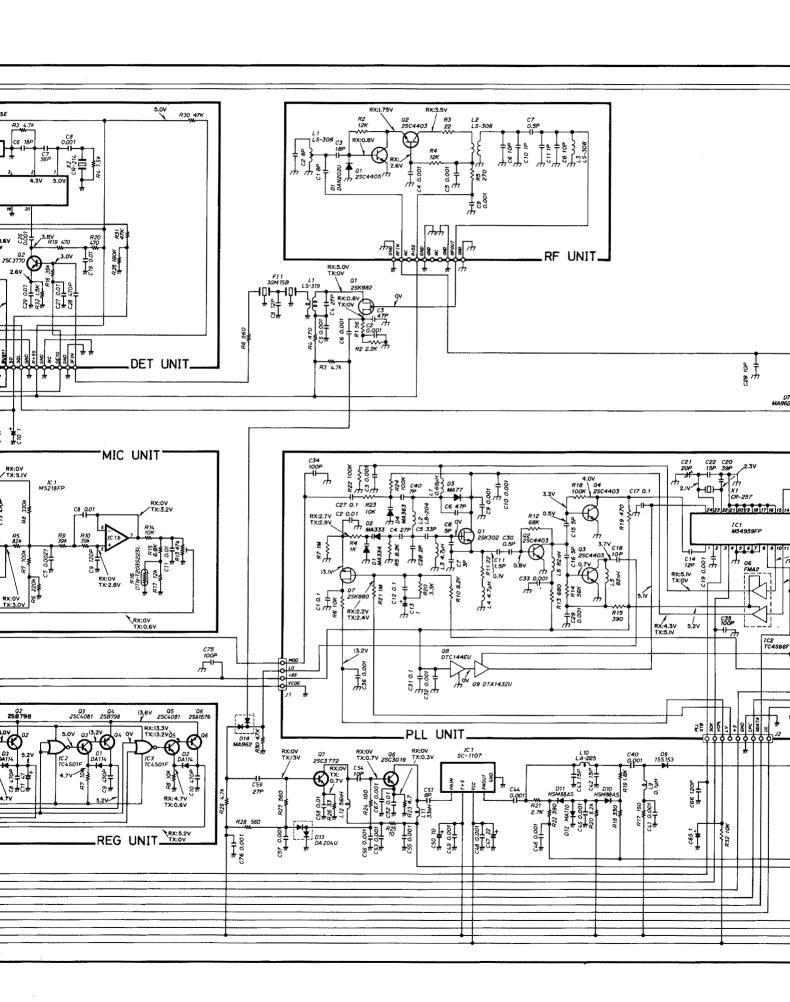


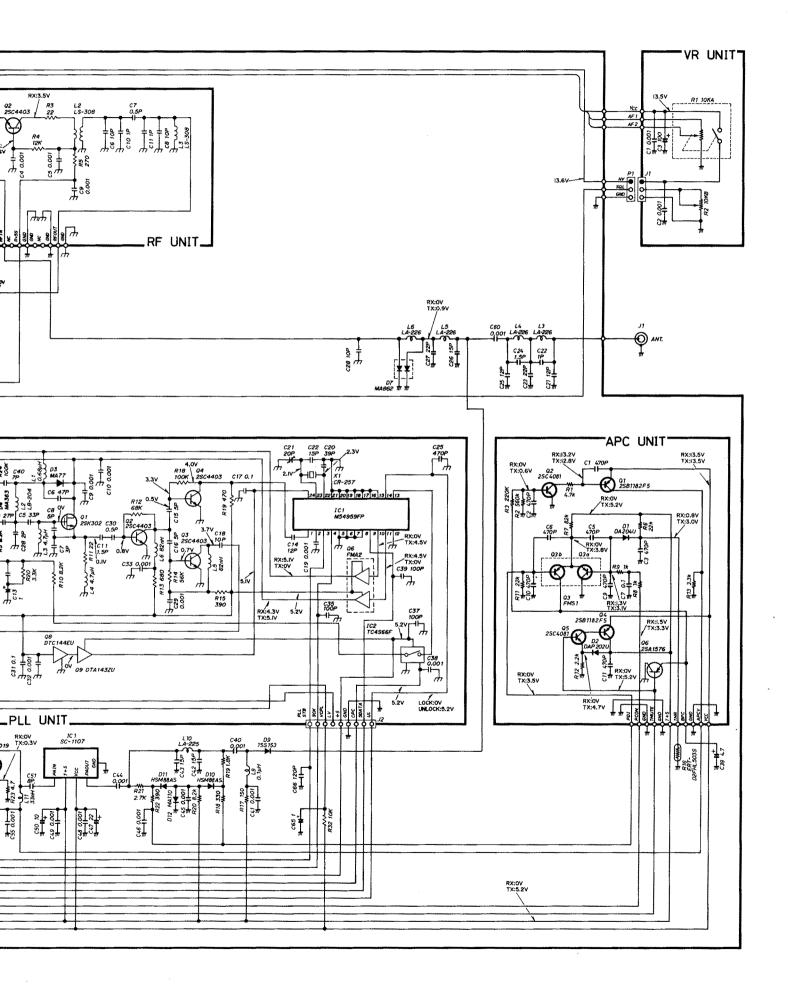
SECTION 10 VOLTAGE DIAGRAM











Icom Inc.

6-9-16, Kamihigashi, Hirano-ku, Osaka 547, Japan

Phone: 06 793 5301 Fax : 06 793 0013 Telex: 05277822 ICOMTR J

Icom America Inc.

<Corporate Headquarters>
2380 116th Avenue N.E., Bellevue, WA 98004, U.S.A.
Phone: (206) 454-8155
Fax: (206) 454-1509
Telex: 152210 ICOM AMER BVUE

<Customer Service> Phone: (206) 454-7619

<Regional Customer Service Centers> 3150 Premier Drive, Suite 126, Irving, TX 75063, U.S.A. Phone: (214) 550-7525 Fax : (214) 550-7423

1777 Phoenix Parkway, Suite 201, Atlanta, GA 30349, U.S.A. Phone : (404) 991-6166 Fax : (404) 991-6327

Icom Canada

A Division of Icom America Inc. 3071 #5 Road, Unit 9, Richmond, B.C., V6X 2T4, Canada Phone: (604) 273-7400 Fax : (604) 273-1900

Icom (Europe) GmbH

Communication Equipment
Himmelgeister Str. 100, 4000 Düsseldorf 1, W. Germany
Phone: 0211 346047
Fax : 0211 333639
Telex : 8588082 ICOM D

Icom (Australia) Pty. Ltd.

Incorporated In Victoria
7 Duke Street, Windsor, Victoria, 3181, Australia
Phone: 03 529 7582
Fax: 03 529 8485
Telex: AA 35521 ICOM AS

Icom (UK) Ltd.

Unit 9, Sea St., Herne Bay, Kent, CT6 8LD, U.K. Phone: 0227 363859 Fax : 0227 360155 Telex : 965179 ICOM G

Icom France S.a

120 Route de Revel, BP4063, 31029 Toulouse Cedex, France Phone: 61. 20. 31. 49 Fax : 61. 34. 05. 91 Telex : 521515 ICOM FRA

Count on us!		